

TMS470R1VF55BA

16/32-BIT RISC FLASH MICROCONTROLLER

SPNS087A – AUGUST 2003 – REVISED AUGUST 2004

- High-Performance Static CMOS Technology
- TMS470R1x 16/32-Bit RISC Core (ARM7TDMI™)
 - 24-MHz System Clock (60-MHz Pipeline Mode)
 - Independent 16/32-Bit Instruction Set
 - Open Architecture With Third-Party Support
 - Built-In Debug Module
 - Utilizes Big-Endian Format
- Integrated Memory
 - 768K-Byte Program Flash
 - 3 Banks With 18 Contiguous Sectors
 - Internal State Machine for Programming and Erase
 - 48K-Byte Static RAM (SRAM)
- Operating Features
 - Core Supply Voltage (V_{CC}): 1.81 - 2.05 V
 - I/O Supply Voltage (V_{CCIO}): 3.0 - 3.6 V
 - Low-Power Modes: STANDBY and HALT
 - Industrial and Automotive Temperature Ranges
- 470+ System Module
 - 32-Bit Address Space Decoding
 - Bus Supervision for Memory and Peripherals
 - Analog Watchdog (AWD) Timer
 - Real-Time Interrupt (RTI)
 - System Integrity and Failure Detection
 - Interrupt Expansion Module (IEM)
- Direct Memory Access (DMA) Controller
 - 32 Control Packets and 16 Channels
- Zero-Pin Phase-Locked Loop (ZPLL)-Based Clock Module With Prescaler
 - Multiply-by-4 or -8 Internal ZPLL Option
 - ZPLL Bypass Mode
- Ten Communication Interfaces:
 - Five Serial Peripheral Interfaces (SPIs)
 - 255 Programmable Baud Rates
 - Two Serial Communications Interfaces (SCIs)
 - 2^{24} Selectable Baud Rates
 - Asynchronous/Isosynchronous Modes
 - Three High-End CAN Controllers (HECCs)
 - 32-Mailbox Capacity Each
 - Fully Compliant With CAN Protocol, Version 2.0B
- High-End Timer (HET)
 - 32 Programmable I/O Channels:
 - 24 High-Resolution Pins
 - 8 Standard-Resolution Pins
 - High-Resolution Share Feature (XOR)
 - High-End Timer RAM
 - 128-Instruction Capacity
- 16-Channel 10-Bit Multi-Buffered ADC (MibADC)
 - 256-Word FIFO Buffer
 - Single- or Continuous-Conversion Modes
 - 1.55 μ s Minimum Sample and Conversion Time
 - Calibration Mode and Self-Test Features
- Eight External Interrupts
- Flexible Interrupt Handling
- 15 Dedicated GIO Pins, 1 Input-Only GIO Pin, and 71 Additional Peripheral I/Os
- External Clock Prescale (ECP) Module
 - Programmable Low-Frequency External Clock (CLK)
- Compatible ROM Device (Planned)
- On-Chip Scan-Base Emulation Logic, IEEE Standard 1149.1[†] (JTAG) Test-Access Port
- 144-Pin Plastic Low-Profile Quad Flatpack (PGE Suffix)
- Development System Support Tools Available
 - Code Composer Studio™ Integrated Development Environment (IDE)
 - HET Assembler and Simulator
 - Real-Time In-Circuit Emulation
 - Flash Programming



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[†] The test-access port is compatible with the IEEE Standard 1149.1-1990, *IEEE Standard Test-Access Port and Boundary Scan Architecture* specification. Boundary scan is not supported on this device.

PRODUCTION DATA information is current as of publication date. Products conform to specifications per the Texas Instruments standard warranty. Production processing does not necessarily include testing of all parameters.



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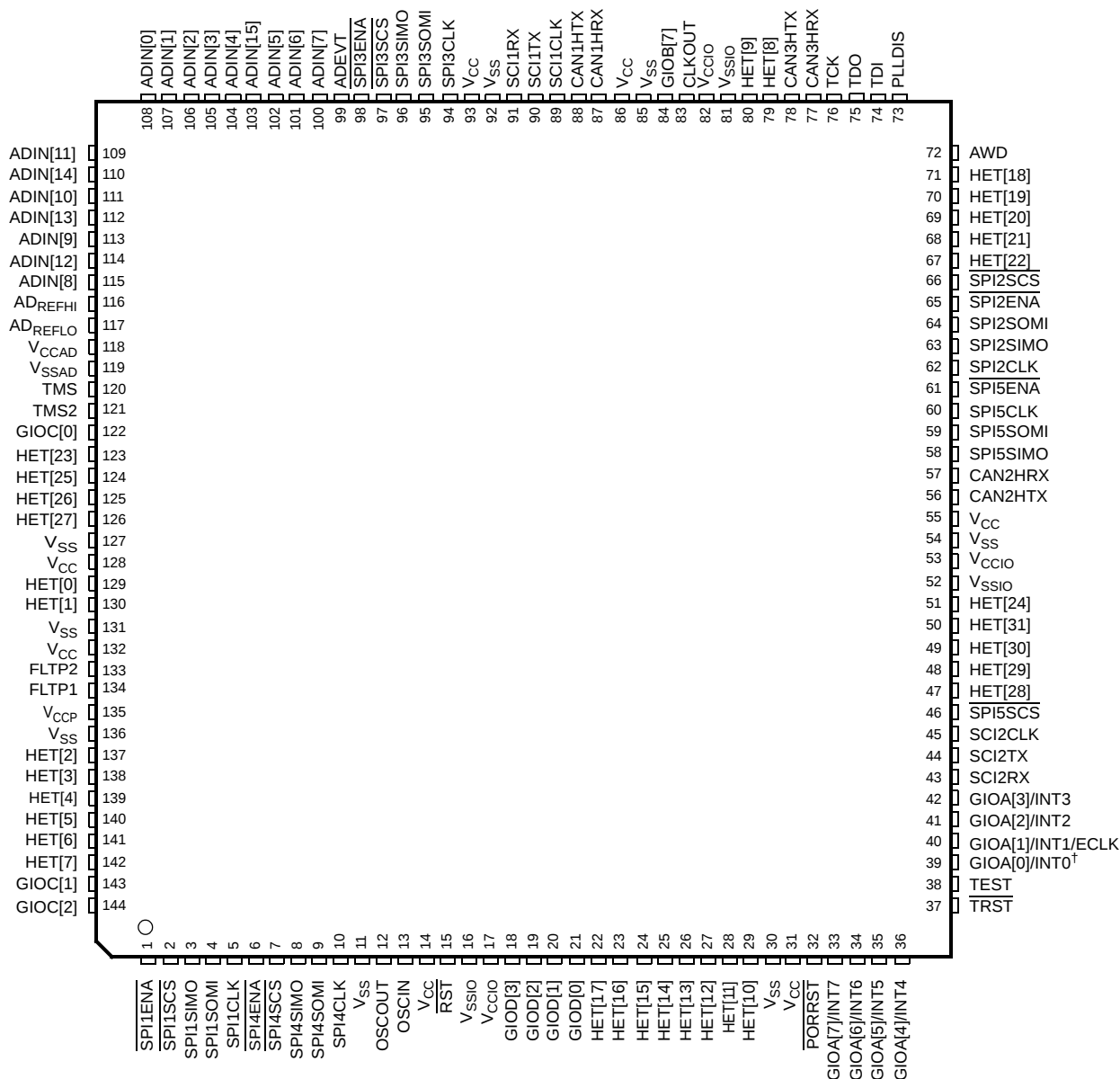
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TMS470R1VF55BA 144-PIN PGE PACKAGE (TOP VIEW)



[†] GIOA[0]/INT0 (pin 39) is an input-only GIO pin.

description

The TMS470R1VF55BA[†] device is a member of the Texas Instruments (TI) TMS470R1x family of general-purpose 16/32-bit reduced instruction set computer (RISC) microcontrollers. The VF55BA microcontroller offers high performance utilizing the high-speed ARM7TDMI 16/32-bit RISC central processing unit (CPU), resulting in a high instruction throughput while maintaining greater code efficiency. The ARM7TDMI 16/32-bit RISC CPU views memory as a linear collection of bytes numbered upwards from zero. The TMS470R1VF55BA utilizes the big-endian format where the most significant byte of a word is stored at the lowest numbered byte and the least significant byte at the highest numbered byte.

High-end embedded control applications demand more performance from their controllers while maintaining low costs. The VF55BA RISC core architecture offers solutions to these performance and cost demands while maintaining low power consumption.

The VF55BA device contains the following:

- ARM7TDMI 16/32-Bit RISC CPU
- TMS470R1x system module (SYS) with 470+ enhancements [including an interrupt expansion module (IEM) and a 16-channel direct-memory access (DMA) controller]
- 768K-byte Flash
- 48K-byte SRAM
- Zero-pin phase-locked loop (ZPLL) clock module
- Analog watchdog (AWD) timer
- Real-time interrupt (RTI) module
- Five serial peripheral interface (SPI) modules
- Two serial communications interface (SCI) modules
- Three high-end CAN controller (HECC) modules
- 10-bit multi-buffered analog-to-digital converter (MibADC) with 16 input channels
- High-end timer (HET) controlling 32 I/Os
- External clock prescale (ECP) module
- Up to 86 I/O pins and 1 input-only pin

The functions performed by the 470+ system module (SYS) include: address decoding; memory protection; memory and peripherals bus supervision; reset and abort exception management; expanded interrupt capability with prioritization for all internal interrupt sources; device clock control; direct-memory access and control; and parallel signature analysis (PSA). This data sheet includes device-specific information such as memory and peripheral select assignment, interrupt priority, and a device memory map. For a more detailed functional description of the SYS module, see the *TMS470R1x System Module Reference Guide* (literature number SPNU189). For a more detailed functional description of the IEM module, see the *TMS470R1x Interrupt Expansion Module (IEM) Reference Guide* (literature number SPNU211). And for a more detailed functional description of the DMA module, see the *TMS470R1x Direct-Memory Access (DMA) Controller Reference Guide* (literature number SPNU210).

The VF55BA memory includes general-purpose SRAM supporting single-cycle read/write accesses in byte, half-word, and word modes.

The Flash memory on this device is a nonvolatile, electrically erasable and programmable memory implemented with a 32-bit-wide data bus interface. The Flash operates with a system clock frequency of up to 24 MHz. When in pipeline mode, the Flash operates with a system clock frequency of up to 60 MHz. For more detailed information on the F05 devices Flash, see the *F05 Flash* section of this data sheet and the *TMS470R1x F05 Flash Reference Guide* (literature number SPNU213).

[†] Throughout the remainder of this document, TMS470R1VF55BA shall be referred to as either the full device name or VF55BA.

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description (continued)

The VF55BA device has ten communication interfaces: five SPIs, two SCIs, and three HECCs. The SPI provides a convenient method of serial interaction for high-speed communications between similar shift-register type devices. The SCI is a full-duplex, serial I/O interface intended for asynchronous communication between the CPU and other peripherals using the standard Non-Return-to-Zero (NRZ) format. The HECC uses a serial, multimaster communication protocol that efficiently supports distributed real-time control with robust communication rates of up to 1 megabit per second (Mbps). The HECC is ideal for applications operating in noisy and harsh environments (e.g., automotive and industrial fields) that require reliable serial communication or multiplexed wiring. For more detailed functional information on the SPI, SCI, and HECC, see the specific Reference Guides for these modules (literature numbers SPNU195, SPNU196, and SPNU197, respectively).

The HET is an advanced intelligent timer that provides sophisticated timing functions for real-time applications. The timer is software-controlled, using a reduced instruction set, with a specialized timer micromachine and an attached I/O port. The HET can be used for compare, capture, or general-purpose I/O. It is especially well suited for applications requiring multiple sensor information and drive actuators with complex and accurate time pulses. For more detailed functional information on the HET, see the *TMS470R1x High-End Timer (HET) Reference Guide* (literature number SPNU199).

The VF55BA device has a 10-bit-resolution, 16-channel sample-and-hold MibADC. The MibADC channels can be converted individually or can be grouped by software for sequential conversion sequences. There are three separate groupings, two of which are triggerable by an external event. Each sequence can be converted once when triggered or configured for continuous conversion mode. For more detailed functional information on the MibADC, see the *TMS470R1x Multi-Buffered Analog-to-Digital Converter (MibADC) Reference Guide* (literature number SPNU206).

The zero-pin phase-locked loop (ZPLL) clock module contains a phase-locked loop, a clock-monitor circuit, a clock-enable circuit, and a prescaler (with prescale values of 1–8). The function of the ZPLL is to multiply the external frequency reference to a higher frequency for internal use. The ZPLL provides ACLK[†] to the system (SYS) module. The SYS module subsequently provides system clock (SYSCLK), real-time interrupt clock (RTICLK), CPU clock (MCLK), and peripheral interface clock (ICLK) to all other VF55BA device modules. For more detailed functional information on the ZPLL, see the *TMS470R1x Zero-Pin Phase-Locked Loop (ZPLL) Clock Module Reference Guide* (literature number SPNU212).

The VF55BA device also has an external clock prescaler (ECP) module that when enabled, outputs a continuous external clock (ECLK) on a specified GPIO pin. The ECLK frequency is a user-programmable ratio of the peripheral interface clock (ICLK) frequency. For more detailed functional information on the ECP, see the *TMS470R1x External Clock Prescaler (ECP) Reference Guide* (literature number SPNU202).

[†] ACLK should not be confused with the MibADC internal clock, ADCLK. ACLK is the continuous system clock from an external resonator/crystal reference.

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device characteristics

The TMS470R1VF55BA device is a derivative of the F05 system emulation device SE470R1VB8AD. Table 1 identifies all the characteristics of the TMS470R1VF55BA device except the SYSTEM and CPU, which are generic. The COMMENTS column aids the user in software-programming and references device-specific information.

Table 1. Device Characteristics

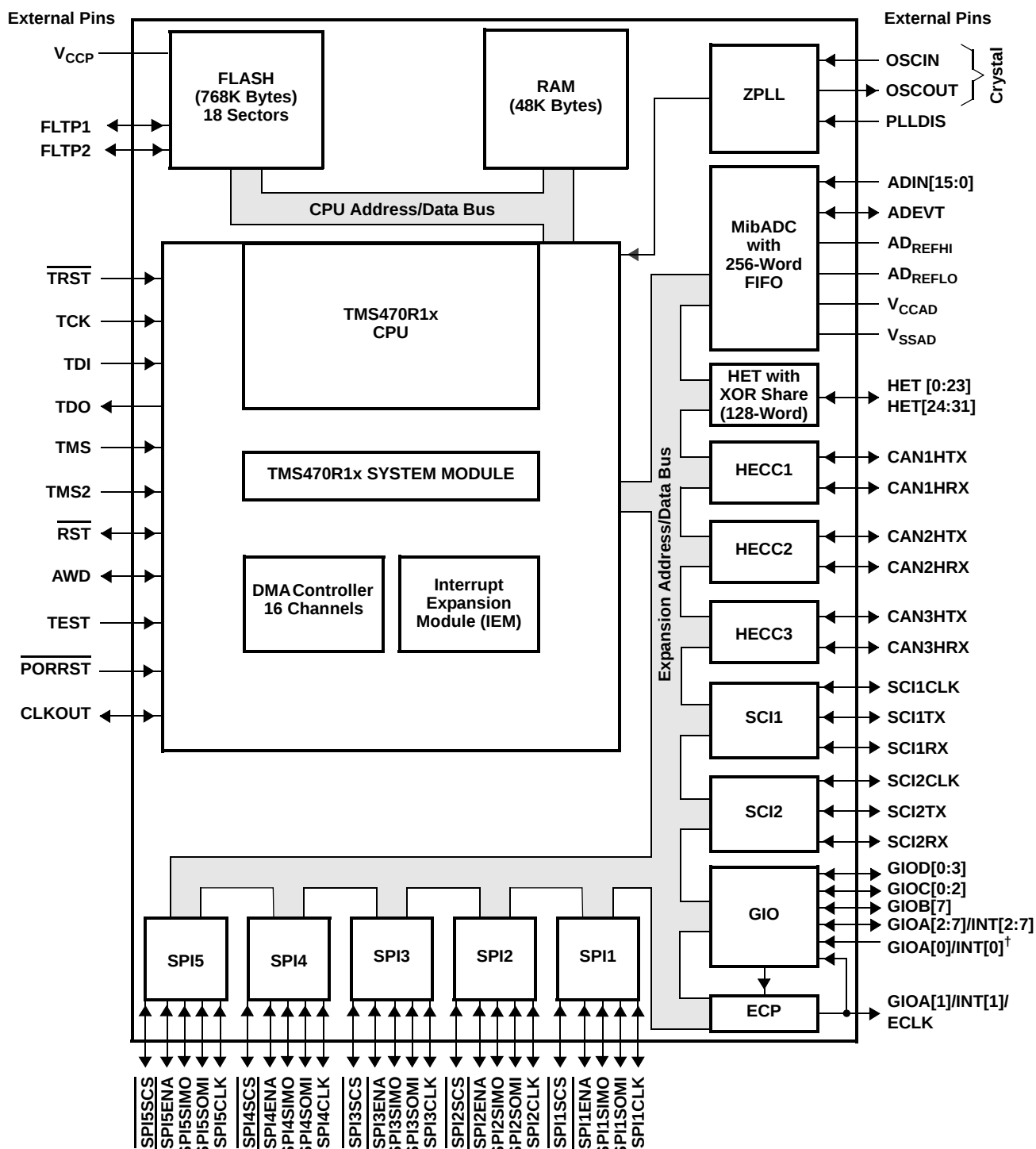
CHARACTERISTICS	DEVICE DESCRIPTION TMS470R1VF55BA	COMMENTS FOR VF55BA
MEMORY		
For the number of memory selects on this device, see the Memory Selection Assignment table (Table 2).		
INTERNAL MEMORY	Pipeline/Non-Pipeline	Flash is pipeline-capable
	768K-Byte Flash 48K-Byte SRAM	The VF55BA RAM is implemented in one 48K array selected by two memory-select signals (see the Memory Selection Assignment table, Table 2).
PERIPHERALS		
For the device-specific interrupt priority configurations, see the Interrupt Priority (IEM and CIM) table (Table 6). And for the 1K peripheral address ranges and their peripheral selects, see the VF55BA Peripherals, System Module, and Flash Base Addresses table (Table 4).		
CLOCK	ZPLL	Zero-pin PLL has no external loop filter pins.
GENERAL-PURPOSE I/Os	15 I/O 1 Input only	In VF55BA, port A has eight (8) external pins, port B has one (1), port C has three (3), and port D has four (4).
ECP	YES	
SCI	2 (3-pin)	SCI1 and SCI2
CAN (HECC and/or SCC)	3 HECCs	Three HECCs (HECC1, HECC2, and HECC3)
SPI (5-pin, 4-pin or 3-pin)	5 (5-pin)	SPI1, SPI2, SPI3, SPI4, and SPI5 (VF55BA)
HET with XOR Share	32 I/O	The VF55BA device has both the logic and registers for a full 32-I/O HET implemented and all 32 pins are available externally. The high-resolution (HR) SHARE feature allows even HR pins to share the next higher odd HR pin structures. This HR sharing is independent of whether or not the odd pin is available externally. If an odd pin is available externally and <i>shared</i> , then the odd pin can only be used as a general-purpose I/O. For more information on HR SHARE, see the <i>TMS470R1x High-End Timer (HET) Reference Guide</i> (literature number SPNU199).
HET RAM	128-Instruction Capacity	
MibADC	10-bit, 16-channel 256-word FIFO	The VF55BA device has both the logic and registers for a full 16-channel MibADC implemented and all 16 pins are available externally.
CORE VOLTAGE	1.81 - 2.05 V	
I/O VOLTAGE	3.0 - 3.6 V	
PINS	144	
PACKAGE	PGE	

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functional block diagram



† GIOA[0]/INT[0] is an input-only GIO pin.

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Terminal Functions

TERMINAL NAME		NO.	TYPE ^{†‡}	INTERNAL PULLUP/ PULLDOWN [§]	DESCRIPTION
HIGH-END TIMER (HET)					
HET[0]	129	3.3-V I/O	IPD		The VF55BA device has both the logic and registers for a full 32-I/O HET implemented and all 32 pins are available externally. Timer input capture or output compare. The HET[31:0] applicable pins can be programmed as general-purpose input/output (GIO) pins. HET[23:0] are high-resolution pins and HET[31:24] are standard-resolution pins. The high-resolution (HR) SHARE feature allows even HR pins to share the next higher odd HR pin structures. This HR sharing is independent of whether or not the odd pin is available externally. If an odd pin is available externally and <i>shared</i> , then the odd pin can only be used as a general-purpose I/O. For more information on HR SHARE, see the <i>TMS470R1x High-End Timer (HET) Reference Guide</i> (literature number SPNU199).
HET[1]	130				
HET[2]	137				
HET[3]	138				
HET[4]	139				
HET[5]	140				
HET[6]	141				
HET[7]	142				
HET[8]	79				
HET[9]	80				
HET[10]	29				
HET[11]	28				
HET[12]	27				
HET[13]	26				
HET[14]	25				
HET[15]	24				
HET[16]	23				
HET[17]	22				
HET[18]	71				
HET[19]	70				
HET[20]	69				
HET[21]	68				
HET[22]	67				
HET[23]	123				
HET[24]	51				
HET[25]	124				
HET[26]	125				
HET[27]	126				
HET[28]	47				
HET[29]	48				
HET[30]	49				
HET[31]	50				
HIGH-END CAN CONTROLLER 1 (HECC1)					
CAN1HTX	88	3.3-V I/O	IPU		HECC1 transmit pin or GIO pin
CAN1HRX	87	3.3-V I/O			HECC1 receive pin or GIO pin
HIGH-END CAN CONTROLLER 2 (HECC2)					
CAN2HTX	56	3.3-V I/O	IPU		HECC2 transmit pin or GIO pin
CAN2HRX	57	3.3-V I/O			HECC2 receive pin or GIO pin
HIGH-END CAN CONTROLLER 3 (HECC3)					
CAN3HTX	78	3.3 V I/O	IPU		HECC3 transmit pin or GIO pin
CAN3HRX	77	3.3 V I/O			HECC3 receive pin or GIO pin

[†] I = input, O = output, PWR = power, GND = ground, REF = reference voltage, NC = no connect

[‡] All I/O pins, except RST, are configured as inputs while PORRST is low and immediately after PORRST goes high.

[§] IPD = internal pulldown, IPU = internal pullup (all internal pullups and pulldowns are active on input pins, independent of the PORRST state.)



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Terminal Functions (Continued)

TERMINAL NAME		NO.	TYPE ^{†‡}	INTERNAL PULLUP/ PULLDOWN [§]	DESCRIPTION
GENERAL-PURPOSE I/O (GIO)					
GIOA[0]/INT0	39	3.3-V I	3.3-V I/O	IPD	General-purpose input/output pins. GIOA[0]/INT0 is an input-only pin. GIOA[7:0]/INT[7:0] are interrupt-capable pins. The GIOA[1]/INT1/ECLK pin is multiplexed with the external clock-out function of the external clock prescale (ECP) module.
GIOA[1]/INT1/ECLK	40				
GIOA[2]/INT2	41				
GIOA[3]/INT3	42				
GIOA[4]/INT4	36				
GIOA[5]/INT5	35				
GIOA[6]/INT6	34				
GIOA[7]/INT7	33				
GIOB[7]	84				
GIOC[0]	122				
GIOC[1]	143				
GIOC[2]	144				
GIOD[0]	21				
GIOD[1]	20				
GIOD[2]	19				
GIOD[3]	18				
MULTI-BUFFERED ANALOG-TO-DIGITAL CONVERTER (MibADC)					
ADEVT	99	3.3-V I/O	IPD	MibADC event input. ADEVT can be programmed as a GIO pin.	
ADIN[0]	108	3.3-V I		MibADC analog input pins	
ADIN[1]	107				
ADIN[2]	106				
ADIN[3]	105				
ADIN[4]	104				
ADIN[5]	102				
ADIN[6]	101				
ADIN[7]	100				
ADIN[8]	115				
ADIN[9]	113				
ADIN[10]	111				

[†] I = input, O = output, PWR = power, GND = ground, REF = reference voltage, NC = no connect

[‡] All I/O pins, except RST, are configured as inputs while PORRST is low and immediately after PORRST goes high.

[§] IPD = internal pulldown, IPU = internal pullup (all internal pullups and pulldowns are active on input pins, independent of the PORRST state.)



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Terminal Functions (Continued)

TERMINAL NAME	NO.	TYPE†‡	INTERNAL PULLUP/ PULLDOWN§	DESCRIPTION
MULTI-BUFFERED ANALOG-TO-DIGITAL CONVERTER (MibADC) (CONTINUED)				
ADIN[11]	109	3.3-V I		MibADC analog input pins
ADIN[12]	114			
ADIN[13]	112			
ADIN[14]	110			
ADIN[15]	103			
AD _{REFHI}	116	3.3-V REF I		MibADC module high-voltage reference input
AD _{REFLO}	117	GND REF I		MibADC module low-voltage reference input
V _{CCAD}	118	3.3-V PWR		MibADC analog supply voltage
V _{SSAD}	119	GND		MibADC analog ground reference
SERIAL PERIPHERAL INTERFACE 1 (SPI1)				
SPI1CLK	5	3.3-V I/O	IPD	SPI1 clock. SPI1CLK can be programmed as a GIO pin.
SPI1ENA	1			SPI1 chip enable. SPI1ENA can be programmed as a GIO pin.
SPI1SCS	2			SPI1 slave chip select. SPI1SCS can be programmed as a GIO pin.
SPI1SIMO	3			SPI1 data stream. Slave in/master out. Can be programmed as a GIO pin.
SPI1SOMI	4			SPI1 data stream. Slave out/master in. Can be programmed as a GIO pin.
SERIAL PERIPHERAL INTERFACE 2 (SPI2)				
SPI2CLK	62	3.3-V I/O	IPD	SPI2 clock. SPI2CLK can be programmed as a GIO pin.
SPI2ENA	65			SPI2 chip enable. SPI2ENA can be programmed as a GIO pin.
SPI2SCS	66			SPI2 slave chip select. SPI2SCS can be programmed as a GIO pin.
SPI2SIMO	63			SPI2 data stream. Slave in/master out. Can be programmed as a GIO pin.
SPI2SOMI	64			SPI2 data stream. Slave out/master in. Can be programmed as a GIO pin.
SERIAL PERIPHERAL INTERFACE 3 (SPI3)				
SPI3CLK	94	3.3-V I/O	IPD	SPI3 clock. SPI3CLK can be programmed as a GIO pin.
SPI3ENA	98			SPI3 chip enable. SPI3ENA can be programmed as a GIO pin.
SPI3SCS	97			SPI3 slave chip select. SPI3SCS can be programmed as a GIO pin.
SPI3SIMO	96			SPI3 data stream. Slave in/master out. Can be programmed as a GIO pin.
SPI3SOMI	95			SPI3 data stream. Slave out/master in. Can be programmed as a GIO pin.
SERIAL PERIPHERAL INTERFACE 4 (SPI4)				
SPI4CLK	10	3.3-V I/O	IPD	SPI4 clock. SPI4CLK can be programmed as a GIO pin.
SPI4ENA	6			SPI4 chip enable. SPI4ENA can be programmed as a GIO pin.
SPI4SCS	7			SPI4 slave chip select. SPI4SCS can be programmed as a GIO pin.
SPI4SIMO	8			SPI4 data stream. Slave in/master out. Can be programmed as a GIO pin.
SPI4SOMI	9			SPI4 data stream. Slave out/master in. Can be programmed as a GIO pin.

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[‡] All I/O pins, except RST, are configured as inputs while PORRST is low and immediately after PORRST goes high.

[§] IPD = internal pulldown, IPU = internal pullup (all internal pullups and pulldowns are active on input pins, independent of the PORRST state).



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Terminal Functions (Continued)

TERMINAL NAME	NO.	TYPE ^{†‡}	INTERNAL PULLUP/ PULLDOWN [§]	DESCRIPTION
SERIAL PERIPHERAL INTERFACE 5 (SPI5)				
SPI5CLK	60	3.3-V I/O	IPD	SPI5 clock. SPI5CLK can be programmed as a GIO pin.
SPI5ENA	61			SPI5 chip enable. SPI5ENA can be programmed as a GIO pin.
SPI5SCS	46			SPI5 slave chip select. SPI5SCS can be programmed as a GIO pin.
SPI5SIMO	58			SPI5 data stream. Slave in/master out. Can be programmed as a GIO pin.
SPI5SOMI	59			SPI5 data stream. Slave out/master in. Can be programmed as a GIO pin.
ZERO-PIN PHASE-LOCKED LOOP (ZPLL)				
OSCIN	13	1.8-V I		Crystal connection pin or external clock input
OSCOUT	12	1.8-V O		External crystal connection pin
PLLDIS	73	3.3-V I	IPD	Enable/disable the ZPLL. The ZPLL can be bypassed and the oscillator becomes the system clock. If not in bypass mode, TI recommends that this pin be connected to ground or pulled down to ground by an external resistor.
SERIAL COMMUNICATIONS INTERFACE 1 (SCI1)				
SCI1CLK	89	3.3-V I/O	IPD	SCI1 clock. SCI1CLK can be programmed as a GIO pin.
SCI1RX	91	3.3-V I/O	IPU	SCI1 data receive. SCI1RX can be programmed as a GIO pin.
SCI1TX	90	3.3-V I/O	IPU	SCI1 data transmit. SCI1TX can be programmed as a GIO pin.
SERIAL COMMUNICATIONS INTERFACE 2 (SCI2)				
SCI2CLK	45	3.3-V I/O	IPD	SCI2 clock. SCI2CLK can be programmed as a GIO pin.
SCI2RX	43	3.3-V I/O	IPU	SCI2 data receive. SCI2RX can be programmed as a GIO pin.
SCI2TX	44	3.3-V I/O	IPU	SCI2 data transmit. SCI2TX can be programmed as a GIO pin.
SYSTEM MODULE (SYS)				
CLKOUT	83	3.3-V I/O	IPD	Bidirectional pin. CLKOUT can be programmed as a GIO pin or the output of SYSCLK, ICLK, or MCLK.
PORRST	32	3.3-V I	IPD	Input master chip power-up reset. External V _{CC} monitor circuitry must assert a power-on reset.
RST	15	3.3-V I/O	IPU	Bidirectional reset. The internal circuitry can assert a reset, and an external system reset can assert a device reset. On this pin, the output buffer is implemented as an open drain (drives low only). To ensure an external reset is not arbitrarily generated, TI recommends that an external pullup resistor be connected to this pin.
WATCHDOG/REAL-TIME INTERRUPT (WD/RTI)				
AWD	72	3.3-V I/O	IPD	Analog watchdog reset. The AWD pin provides a system reset if the WD KEY is not written in time by the system, providing an external RC network circuit is connected. If the user is not using AWD, TI recommends that this pin be connected to ground or pulled down to ground by an external resistor. For more details on the external RC network circuit, see the <i>TMS470R1x System Module Reference Guide</i> (literature number SPNU189) and the application note <i>Analog Watchdog Resistor, Capacitor and Discharge Interval Selection Constraints</i> (literature number SPNA005).
TEST/DEBUG (T/D)				
TCK	76	3.3-V I	IPD	Test clock. TCK controls the test hardware (JTAG)
TDI	74	3.3-V I	IPU	Test data in. TDI inputs serial data to the test instruction register, test data register, and programmable test address (JTAG).
TDO	75	3.3-V O	IPD	Test data out. TDO outputs serial data from the test instruction register, test data register, identification register, and programmable test address (JTAG).

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Terminal Functions (Continued)

TERMINAL NAME		NO.	TYPE ^{†‡}	INTERNAL PULLUP/ PULLDOWN [§]	DESCRIPTION
TEST/DEBUG (T/D) (CONTINUED)					
TEST	38	3.3-V I	IPD	Test enable. Reserved for internal use only. TI recommends that this pin be connected to ground or pulled down to ground by an external resistor.	
TMS	120	3.3-V I	IPU	Serial input for controlling the state of the CPU test access port (TAP) controller (JTAG).	
TMS2	121	3.3-V I	IPU	Serial input for controlling the second TAP. TI recommends that this pin be connected to V _{CCIO} or pulled up to V _{CCIO} by an external resistor.	
$\overline{\text{TRST}}$	37	3.3-V I	IPD	Test hardware reset to TAP1 and TAP2. IEEE Standard 1149-1 (JTAG) Boundary-Scan Logic. TI recommends that this pin be pulled down to ground by an external resistor.	
FLASH					
FLTP1	134	NC		Flash test pad 1. For proper operation, this pin must not be connected [no connect (NC)].	
FLTP2	133	NC		Flash test pad 2. For proper operation, this pin must not be connected [no connect (NC)].	
V _{CCP}	135	3.3-V PWR		Flash external pump voltage (3.3 V). This pin is required for both Flash read and Flash program and erase operations.	
SUPPLY VOLTAGE CORE (1.8 V)					
V _{CC}	14	1.8-V PWR		Core logic supply voltage	
	31				
	55				
	86				
	93				
	128				
	132				
SUPPLY VOLTAGE DIGITAL I/O (3.3 V)					
V _{CCIO}	17	3.3-V PWR		Digital I/O supply voltage	
	53				
	82				
SUPPLY GROUND CORE					
V _{SS}	11	GND		Core supply ground reference	
	30				
	54				
	85				
	92				
	127				
	131				
	136				
SUPPLY GROUND DIGITAL I/O					
V _{SSIO}	16	GND		Digital I/O supply ground reference	
	52				
	81				

† I = input, O = output, PWR = power, GND = ground, REF = reference voltage, NC = no connect

‡ All I/O pins, except RST, are configured as inputs while $\overline{\text{PORRST}}$ is low and immediately after $\overline{\text{PORRST}}$ goes high.

§ IPD = internal pulldown, IPU = internal pullup (all internal pullups and pulldowns are active on input pins, independent of the $\overline{\text{PORRST}}$ state.)



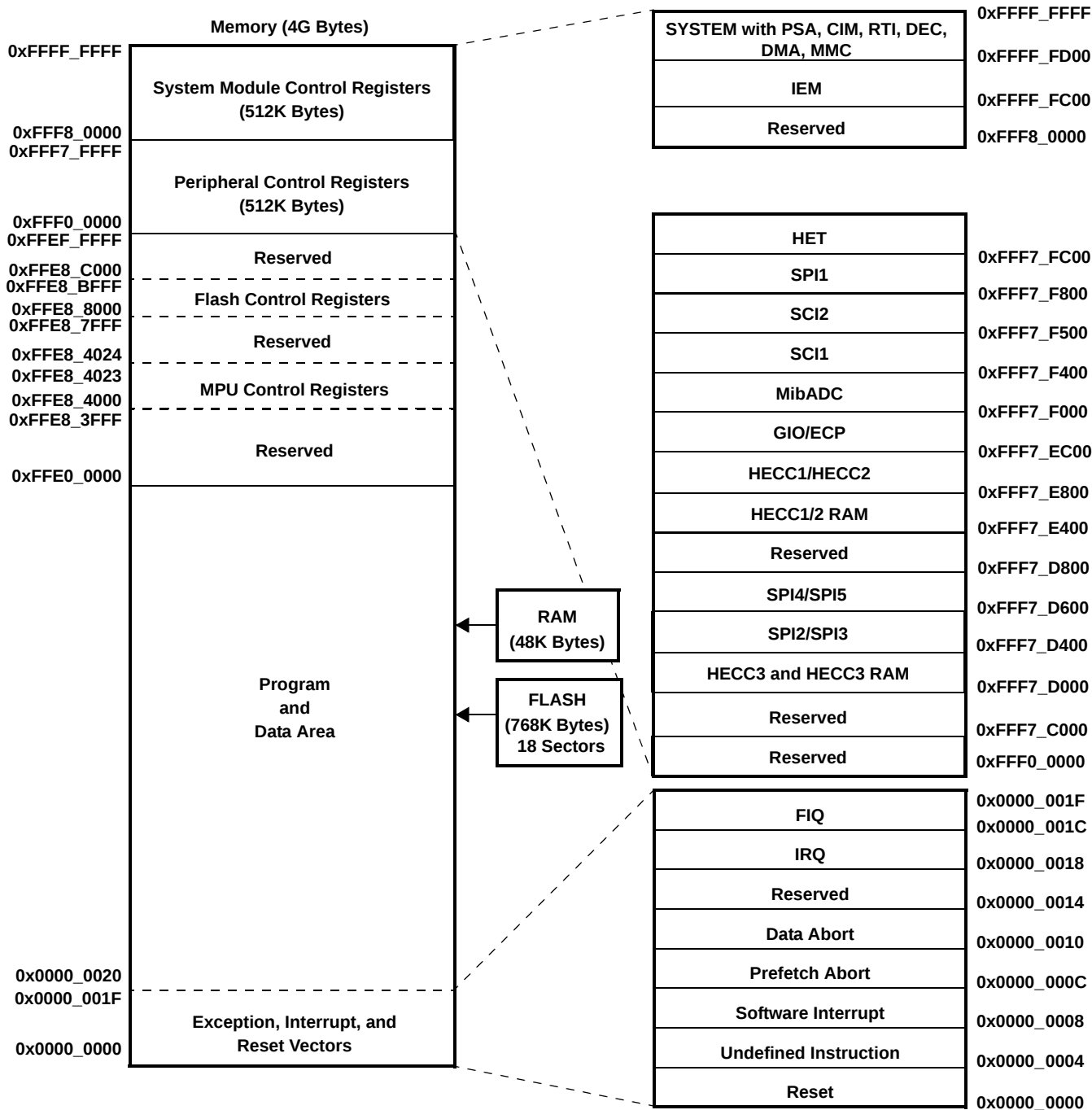
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VF55BA DEVICE-SPECIFIC INFORMATION

memory

Figure 1 shows the memory map of the VF55BA device.



NOTES: A. Memory addresses are configurable by the system (SYS) module within the range of 0x0000_0000 to 0xFFE0_0000.
B. The CPU registers are not a part of the memory map.

Figure 1. Memory Map

memory selects

Memory selects allow the user to address memory arrays (i.e., Flash, RAM, and HET RAM) at user-defined addresses. Each memory select has its own set (low and high) of memory base address registers (MFBAHRx and MFBALRx) that, together, define the array's starting (base) address, block size, and protection.

The base address of each memory select is configurable to any memory address boundary that is a multiple of the decoded block size. For more information on how to control and configure these memory select registers, see the bus structure and memory sections of the *TMS470R1x System Module Reference Guide* (literature number SPNU189).

For the memory selection assignments and the memory selected, see Table 2.

Table 2. Memory Selection Assignment

MEMORY SELECT	MEMORY SELECTED (ALL INTERNAL)	MEMORY SIZE	MPU	MEMORY BASE ADDRESS REGISTER	STATIC MEM CTL REGISTER
0 (fine)	FLASH	768K	NO	MFBAHR0 and MFBALR0	
1 (fine)	FLASH		NO	MFBAHR1 and MFBALR1	
2 (fine)	RAM	48K [†]	YES	MFBAHR2 and MFBALR2	
3 (fine)	RAM		YES	MFBAHR3 and MFBALR3	
4 (fine)	HET RAM	1.5K		MFBAHR4 and MFBALR4	SMCR1

[†] The starting addresses for both RAM memory-select signals *cannot* be offset from each other by a multiple of the user-defined block size in the memory-base address register.

RAM

The VF55BA device contains 48K bytes of internal static RAM configurable by the SYS module to be addressed within the range of 0x0000_0000 to 0xFFE0_0000. This VF55BA RAM is implemented in one 48 K array selected by two memory-select signals. This VF55BA configuration imposes an additional constraint on the memory map for RAM; the starting addresses for both RAM memory selects *cannot* be offset from each other by the multiples of the size of the physical RAM (i.e., 48K for the VF55BA device). The VF55BA RAM is addressed through memory selects 2 and 3.

The RAM can be protected by the memory protection unit (MPU) portion of the SYS module, allowing the user finer blocks of memory protection than is allowed by the memory selects. The MPU is ideal for protecting an operating system while allowing access to the current task. For more detailed information on the MPU portion of the SYS module and memory protection, see the memory section of the *TMS470R1x System Module Reference Guide* (literature number SPNU189).

F05 Flash

The F05 Flash memory is a nonvolatile electrically erasable and programmable memory implemented with a 32-bit-wide data bus interface. The F05 Flash has an external state machine for program and erase functions. See the *Flash read* and *Flash program and erase* sections below. For more detailed functional information on the F05 Flash module, see the *TMS470R1x F05 Flash Reference Guide* (literature number SPNU213).

flash protection keys

The VF55BA device provides Flash protection keys. These four 32-bit protection keys prevent program/erase/compaction operations from occurring until after the four protection keys have been matched by the CPU loading the correct user keys into the FMPKEY control register. The protection keys on the VF55BA are located in the last 4 words of the first 16K sector. For more detailed information on the Flash protection keys and the FMPKEY control register, see the Optional Quadruple Protection Keys and Programming the Protection Keys portions of the *TMS470R1x F05 Flash Reference Guide* (literature number SPNU213).

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Flash read

The VF55BA Flash memory is configurable by the SYS module to be addressed within the range of 0x0000_0000 to 0xFFE0_0000. The Flash is addressed through memory selects 0 and 1.

Note: The Flash external pump voltage (V_{CCP}) is required for all operations (program, erase, and read).

Flash pipeline mode

When in pipeline mode, the Flash operates with a system clock frequency of up to 60 MHz (versus a system clock in normal mode of up to 24 MHz). Flash in pipeline mode is capable of accessing 64-bit words and provides two 32-bit pipelined words to the CPU. Also in pipeline mode, the Flash can be read with no wait states when memory addresses are contiguous (after the initial 1-or 2-wait-state reads).

Note: After a system reset, pipeline mode is **disabled** (ENPIPE bit [FMREGOPT.0] is a "0"). In other words, the VF55BA device powers up and comes out of reset in non-pipeline mode. Furthermore, setting the Flash configuration mode bit (GLBCTRL.4) will override pipeline mode.

Flash program and erase

The VF55BA device Flash contains three 256K-byte memory arrays (or banks) for a total of 768K bytes of Flash and consists of eighteen sectors. These eighteen sectors are sized as follows:

Table 3. VF55BA Flash Memory Banks and Sectors

SECTOR NO.	SEGMENT	LOW ADDRESS	HIGH ADDRESS	MEMORY ARRAYS (OR BANKS)
0	16K Bytes	0x0000_0000	0x0000_3FFF	BANK0 (256K Bytes)
1	16K Bytes	0x0000_4000	0x0000_7FFF	
2	32K Bytes	0x0000_8000	0x0000_FFFF	
3	32K Bytes	0x0001_0000	0x0001_7FFF	
4	32K Bytes	0x0001_8000	0x0001_FFFF	
5	32K Bytes	0x0002_0000	0x0002_7FFF	
6	32K Bytes	0x0002_8000	0x0002_FFFF	
7	32K Bytes	0x0003_0000	0x0003_7FFF	
8	16K Bytes	0x0003_8000	0x0003_BFFF	
9	16K Bytes	0x0003_C000	0x0003_FFFF	
0	64K Bytes	0x0004_0000	0x0004_FFFF	BANK1 (256K Bytes)
1	64K Bytes	0x0005_0000	0x0005_FFFF	
2	64K Bytes	0x0006_0000	0x0006_FFFF	
3	64K Bytes	0x0007_0000	0x0007_FFFF	
0	64K Bytes	0x0008_0000	0x0008_FFFF	BANK2 (256K Bytes)
1	64K Bytes	0x0009_0000	0x0009_FFFF	
2	64K Bytes	0x000A_0000	0x000A_FFFF	
3	64K Bytes	0x000B_0000	0x000B_FFFF	

The minimum size for an erase operation is one sector. The maximum size for a program operation is one 16-bit word.

Note: The Flash external pump voltage (V_{CCP}) is required for all operations (program, erase, and read).

For more detailed information on Flash program and erase operations, see the *TMS470R1x F05 Flash Reference Guide* (literature number SPNU213).

HET RAM

The VF55BA device contains HET RAM. The HET RAM has a 128-instruction capability. The HET RAM is configurable by the SYS module to be addressed within the range of 0x0000_0000 to 0xFFE0_0000. The HET RAM is addressed through memory select 4.

XOR share

The VF55BA HET peripheral contains the XOR-share feature. This feature allows two adjacent HET high-resolution channels to be XORED together, making it possible to output smaller pulses than a standard HET. For more detailed information on the HET XOR-share feature, see the *TMS470R1x High-End Timer (HET) Reference Guide* (literature number SPNU199).

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peripheral selects and base addresses

The VF55BA device uses eight of the sixteen peripheral selects to decode the base addresses of the peripherals. These peripheral selects are fixed and transparent to the user since they are part of the decoding scheme used by the SYS module.

Control registers for the peripherals, SYS module, and Flash begin at the base addresses shown in Table 4.

Table 4. VF55BA Peripherals, System Module, and Flash Base Addresses

CONNECTING MODULE	ADDRESS RANGE		PERIPHERAL SELECTS
	BASE ADDRESS	ENDING ADDRESS	
SYSTEM	0xFFFF_FFD0	0xFFFF_FFFF	N/A
RESERVED	0xFFFF_FF60	0xFFFF_FFCF	N/A
PSA	0xFFFF_FF40	0xFFFF_FF5F	N/A
CIM	0xFFFF_FF20	0xFFFF_FF3F	N/A
RTI	0xFFFF_FF00	0xFFFF_FF1F	N/A
DMA	0xFFFF_FE80	0xFFFF_FEFF	N/A
DEC	0xFFFF_FE00	0xFFFF_FE7F	N/A
MMC	0xFFFF_FD00	0xFFFF_FD7F	N/A
IEM	0xFFFF_FC00	0xFFFF_FCFE	N/A
RESERVED	0xFFFF_0000	0xFFFF_FBFF	N/A
RESERVED	0xFFFF_FD00	0xFFFF_FFFF	PS[0]
HET	0xFFFF_FC00	0xFFFF_FCFE	
RESERVED	0xFFFF_F900	0xFFFF_FBFF	PS[1]
SPI1	0xFFFF_F800	0xFFFF_F8FF	
RESERVED	0xFFFF_F600	0xFFFF_F7FF	PS[2]
SCI2	0xFFFF_F500	0xFFFF_F5FF	
SCI1	0xFFFF_F400	0xFFFF_F4FF	
RESERVED	0xFFFF_F100	0xFFFF_F3FF	PS[3]
MibADC	0xFFFF_F000	0xFFFF_F0FF	
ECP	0xFFFF_EF00	0xFFFF_EFFF	PS[4]
RESERVED	0xFFFF_ED00	0xFFFF_EEFF	
GIO	0xFFFF_EC00	0xFFFF_ECFE	
HECC2	0xFFFF_EA00	0xFFFF_EBFF	PS[5]
HECC1	0xFFFF_E800	0xFFFF_E9FF	
HECC2 RAM	0xFFFF_E600	0xFFFF_E7FF	PS[6]
HECC1 RAM	0xFFFF_E400	0xFFFF_E5FF	
RESERVED	0xFFFF_E000	0xFFFF_E3FF	PS[7]
RESERVED	0xFFFF_DC00	0xFFFF_DFFF	PS[8]
RESERVED	0xFFFF_D800	0xFFFF_DBFF	PS[9]
SPI5	0xFFFF_D700	0xFFFF_D7FF	PS[10]
SPI4	0xFFFF_D600	0xFFFF_D6FF	
SPI3	0xFFFF_D500	0xFFFF_D5FF	
SPI2	0xFFFF_D400	0xFFFF_D4FF	
HECC3 RAM	0xFFFF_D200	0xFFFF_D3FF	PS[11]
HECC3	0xFFFF_D000	0xFFFF_D1FF	
RESERVED	0xFFFF_C000	0xFFFF_CFFF	PS[12]-PS[15]
RESERVED	0xFFFF_0000	0xFFFF_BFFF	N/A
FLASH CONTROL REGISTERS	0xFFE8_8000	0xFFE8_BFFF	N/A
MPU CONTROL REGISTERS	0xFFE8_4000	0xFFE8_4023	N/A

direct-memory access (DMA)

The direct-memory access (DMA) controller transfers data to and from any specified location in the VF55BA memory map (except for restricted memory locations like the system control registers area). The DMA manages up to 16 channels, and supports data transfer for both on-chip and off-chip memories and peripherals. The DMA controller is connected to both the CPU and Peripheral busses, enabling these data transfers to occur in parallel with CPU activity and thus, maximizing overall system performance.

Although the DMA controller has two possible configurations, for the VF55BA device, the DMA controller configuration is 32 control packets and 16 channels.

For the VF55BA DMA request hardwired configuration, see Table 5.

Table 5. DMA Request Lines Connections

MODULES	DMA REQUEST INTERRUPT SOURCES		DMA CHANNEL
RESERVED			DMAREQ[0]
SPI1	SPI1 end-receive	SPI1DMA0	DMAREQ[1]
SPI1	SPI1 end-transmit	SPI1DMA1	DMAREQ[2]
MibADC [†]	MibADC event	MibADCDMA0	DMAREQ[3]
MibADC [†] /SCI1	MibADC G1/SCI1 end-receive	MibADCDMA1/SCI1DMA0	DMAREQ[4]
MibADC [†] /SCI1	MibADC G2/SCI1 end-transmit	MibADCDMA2/SCI1DMA1	DMAREQ[5]
SPI4	SPI4 end-receive	SPI4DMA0	DMAREQ[6]
SPI2	SPI2 end-receive	SPI2DMA0	DMAREQ[7]
SPI2	SPI2 end-transmit	SPI2DMA1	DMAREQ[8]
RESERVED			DMAREQ[9]
RESERVED			DMAREQ[10]
SPI4	SPI4 end-transmit	SPI4DMA1	DMAREQ[11]
SPI5	SPI5 end-receive	SPI5DMA0	DMAREQ[12]
SPI5	SPI5 end-transmit	SPI5DMA1	DMAREQ[13]
SCI2/SPI3	SCI2 end-receive/SPI3 end-receive	SCI2DMA0/SPI3DMA0	DMAREQ[14]
SCI2/SPI3	SCI2 end-transmit/SPI3 end-transmit	SCI2DMA1/SPI3DMA1	DMAREQ[15]

[†] The MibADC is capable of being serviced by the DMA when the device is in buffered mode. For more information on buffered mode, see the MibADC section of this data sheet and the *TMS470R1x Multi-Buffered Analog-to-Digital Converter (MibADC) Reference Guide* (literature number SPNU206).

Each channel has two control packets attached to it, allowing the DMA to continuously load RAM and generate periodic interrupts so that the data can be read by the CPU. The control packets allow for the interrupt enable, and the channels determine the priority level of the interrupt.

DMA transfers occur in one of two modes:

- Non-request mode (used when transferring from memory to memory)
- Request mode (used when transferring from memory to peripheral)

For more detailed functional information on the DMA controller, see the *TMS470R1x Direct Memory Access (DMA) Controller Reference Guide* (literature number SPNU210).

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interrupt priority (IEM to CIM)

Interrupt requests originating from the VF55BA peripheral modules (i.e., SPI1, SPI2, or SPI3; SCI1 or SCI2; HECC1 or HECC2; RTI; etc.) are assigned to channels within the 48-channel interrupt expansion module (IEM) where, via programmable register mapping, these channels are then mapped to the 32-channel central interrupt manager (CIM) portion of the SYS module.

Programming multiple interrupt sources in the IEM to the same CIM channel effectively shares the CIM channel between sources.

The CIM request channels are maskable so that individual channels can be selectively disabled. All interrupt requests can be programmed in the CIM to be of either type:

- Fast interrupt request (FIQ)
- Normal interrupt request (IRQ)

The CIM prioritizes interrupts. The precedences of request channels decrease with ascending channel order in the CIM (0 [highest] and 31 [lowest] priority). For IEM-to-CIM default mapping, channel priorities, and their associated modules, see Table 6.

Table 6. Interrupt Priority (IEM and CIM)

MODULES	INTERRUPT SOURCES	DEFAULT CIM INTERRUPT LEVEL/ CHANNEL	IEM CHANNEL
SPI1	SPI1 end-transfer/overflow	0	0
RTI	COMP2 interrupt	1	1
RTI	COMP1 interrupt	2	2
RTI	TAP interrupt	3	3
SPI2	SPI2 end-transfer/overflow	4	4
GIO	GIO interrupt A	5	5
RESERVED		6	6
HET	HET interrupt 1	7	7
SPI4	SPI4 end-transfer/overflow	8	8
SCI1/SCI2	SCI1 or SCI2 error interrupt	9	9
SCI1	SCI1 receive interrupt	10	10
RESERVED		11	11
SPI5	SPI5 end-transfer/overflow	12	12
HECC1	HECC1 interrupt A	13	13
RESERVED		14	14
SPI3	SPI3 end-transfer/overflow	15	15
MibADC	MibADC end event conversion	16	16
SCI2	SCI2 receive interrupt	17	17
DMA	DMA interrupt 0	18	18
HECC3	HECC3 interrupt A	19	19
SCI1	SCI1 transmit interrupt	20	20
System	SW interrupt (SSI)	21	21
RESERVED		22	22
HET	HET interrupt 2	23	23
HECC1	HECC1 interrupt B	24	24
RESERVED		25	25

interrupt priority (IEM to CIM) (continued)

Table 6. Interrupt Priority (IEM and CIM) (Continued)

MODULES	INTERRUPT SOURCES	DEFAULT CIM INTERRUPT LEVEL/ CHANNEL	IEM CHANNEL
SCI2	SCI2 transmit interrupt	26	26
MibADC	MibADC end Group 1 conversion	27	27
DMA	DMA interrupt 1	28	28
GIO	GIO interrupt B	29	29
MibADC	MibADC end Group 2 conversion	30	30
HECC3	HECC3 interrupt B	31	31
RESERVED		31	32
RESERVED		31	33
RESERVED		31	34
RESERVED		31	35
RESERVED		31	36
RESERVED		31	37
HECC2	HECC2 interrupt A	31	38
HECC2	HECC2 interrupt B	31	39
RESERVED		31	40
RESERVED		31	41
RESERVED		31	42
RESERVED		31	43
RESERVED		31	44
RESERVED		31	45
RESERVED		31	46
RESERVED		31	47

For more detailed functional information on the IEM, see the *TMS470R1x Interrupt Expansion Module (IEM) Reference Guide* (literature number SPNU211). For more detailed functional information on the CIM, see the *TMS470R1x System Module Reference Guide* (literature number SPNU189).

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MibADC

The multi-buffered analog-to-digital converter (MibADC) accepts an analog signal and converts the signal to a 10-bit digital value.

The VF55BA MibADC module can function in two modes: compatibility mode, where its programmer's model is compatible with the TMS470R1x ADC module and its digital results are stored in digital result registers; or in buffered mode, where the digital result registers are replaced with three FIFO buffers, one for each conversion group [event, group1 (G1), and group2 (G2)]. In buffered mode, the MibADC buffers can be serviced by interrupts or by the DMA.

MibADC event trigger enhancements

The MibADC includes two major enhancements over the event-triggering capability of the TMS470R1x ADC.

- Both group1 and the event group can be configured for event-triggered operation, providing up to two event-triggered groups.
- The trigger source and polarity can be selected individually for both group 1 and the event group from the three options identified in Table 7.

Table 7. MibADC Event Hookup Configuration

EVENT #	SOURCE SELECT BITS FOR G1 OR EVENT (G1SRC[1:0] or EVSRC[1:0])	SIGNAL PIN NAME
EVENT1	00	ADEVT
EVENT2	01	HET18
EVENT3	10	HET19
EVENT4	11	N/C

For group 1, these event-triggered selections are configured via the group 1 source select bits (G1SRC[1:0]) in the AD event source register (ADEVTSRC.[5:4]). For the event group, these event-triggered selections are configured via the event group source select bits (EVSRC[1:0]) in the AD event source register (ADEVTSRC.[1:0]).

For more detailed functional information on the MibADC, see the *TMS470R1x Multi-Buffered Analog-to-Digital Converter (MibADC) Reference Guide* (literature number SPNU206).

development system support

Texas Instruments provides extensive hardware and software development support tools for the TMS470R1x family. These support tools include:

- Code Composer Studio™ IDE
 - Fully integrated suite of software development tools
 - Includes Compiler/Assembler/Linker, Debugger, and Simulator
 - Supports Real-Time analysis, data visualization, and open API
- Optimizing C compiler
 - Supports high-level language programming
 - Full implementation of the standard ANSI C language
 - Powerful optimizer that improves code-execution speed and reduces code size
 - Extensive run-time support library included
 - TMS470R1x control registers easily accessible from the C program
 - Interfaces C functions and assembly functions easily
 - Establishes comprehensive, easy-to-use tool set for the development of high-performance microcontroller applications in C/C++
- Assembly language tools (assembler and linker)
 - Provides extensive macro capability
 - Allows high-speed operation
 - Allows extensive control of the assembly process using assembler directives
 - Automatically resolves memory references as C and assembly modules are combined
- TMS470R1x CPU Simulator
 - Provides capability to simulate CPU operation without emulation hardware
 - Allows inspection and modifications of memory locations
 - Allows debugging programs in C or assembly language
- XDS emulation communication kits
 - Allow high-speed JTAG communication to the TMS470R1x emulator or target board

For information on pricing and availability, contact the nearest TI field sales office or authorized distributor.

Code Composer Studio is a trademark of Texas Instruments.



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documentation support

Extensive documentation supports all of the TMS470 microcontroller family generation of devices. The types of documentation available include: data sheets with design specifications; complete user's guides for all devices and development support tools; and hardware and software applications. Useful reference documentation includes:

- User's Guides
 - *TMS470R1x 32-Bit RISC Microcontroller Family User's Guide* (literature number SPNU134)
 - *TMS470R1x C/C++ Compiler User's Guide* (literature number SPNU151)
 - *TMS470R1x Code Generation Tools Getting Started Guide* (literature number SPNU117)
 - *TMS470R1x C Source Debugger User's Guide* (literature number SPNU124)
 - *TMS470R1x Assembly Language Tools User's Guide* (literature number SPNU118)
 - *TMS470R1x System Module Reference Guide* (literature number SPNU189)
 - *TMS470R1x Direct Memory Access (DMA) Reference Guide* (literature number SPNU194)
 - *TMS470R1x Serial Peripheral Interface (SPI) Reference Guide* (literature number SPNU195)
 - *TMS470R1x Serial Communication Interface (SCI) Reference Guide* (literature number SPNU196)
 - *TMS470R1x Controller Area Network (CAN) Reference Guide* (literature number SPNU197)
 - *TMS470R1x High-End Timer (HET) Reference Guide* (literature number SPNU199)
 - *TMS470R1x External Clock Prescale (ECP) Reference Guide* (literature number SPNU202)
 - *TMS470R1x Multi-Buffered Analog-to-Digital Converter (MibADC) Reference Guide* (literature number SPNU206)
 - *TMS470R1x Zero-Pin Phase-Locked Loop (ZPLL) Clock Module Reference Guide* (literature number SPNU212)
 - *TMS470R1x F05 Flash Reference Guide* (literature number SPNU213)
- Application Reports:
 - *Analog Watchdog Resistor, Capacitor and Discharge Interval Selection Constraints* (literature number SPNA005)
 - *F05/C05 Power Up Reset and Power Sequencing Requirements* (literature number SPNA009)

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device numbering conventions

Figure 2 illustrates the numbering and symbol nomenclature for the TMS470R1x family.

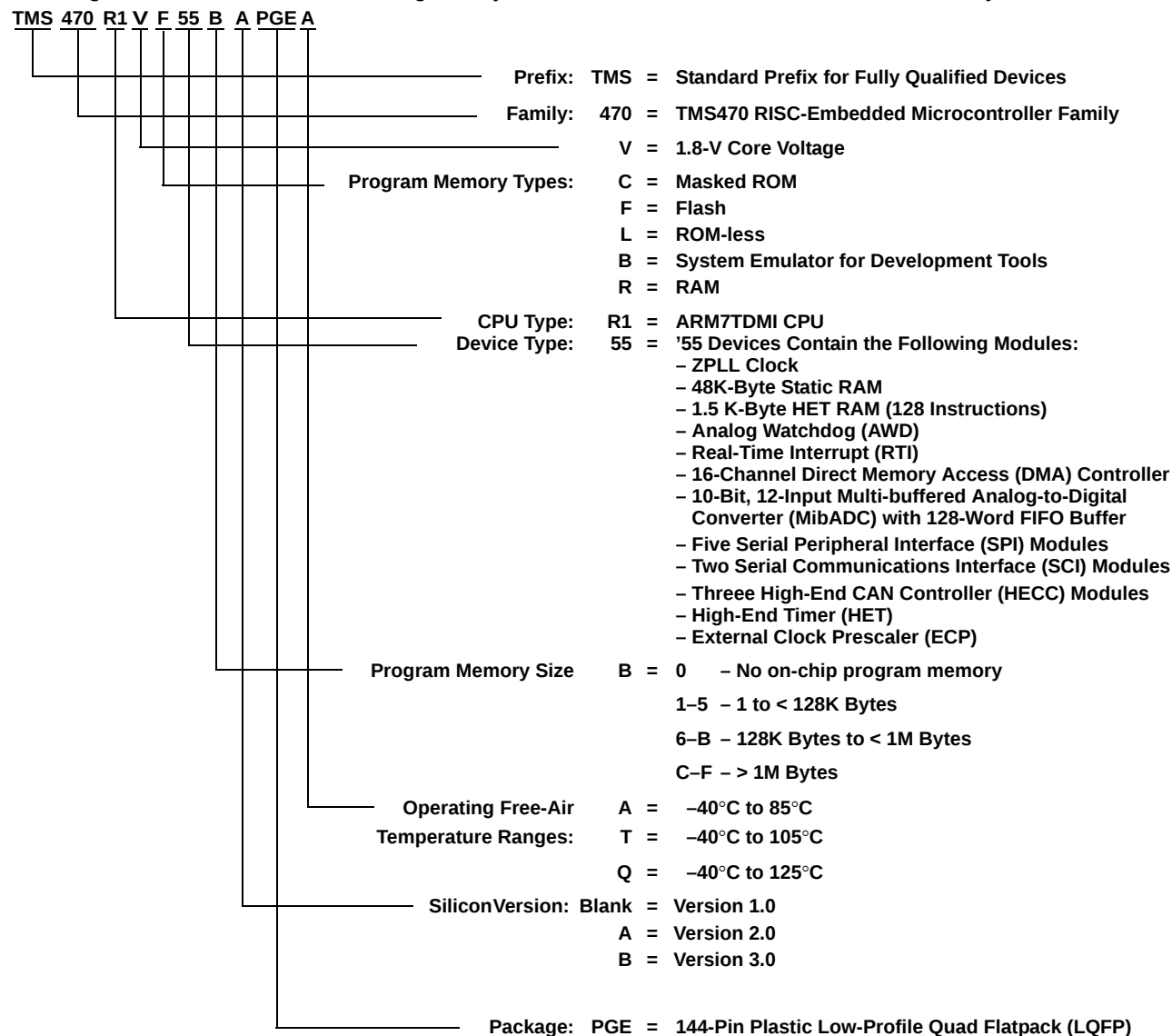


Figure 2. TMS470R1x Family Nomenclature

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device identification code register

The device identification code register identifies the silicon version, the technology family (TF), a ROM or Flash device, and an assigned device-specific part number (see Table 8). The VF55BA device identification code register value is 0x087Fh.

Table 8. TMS470 Device ID Bit Allocation Register

BIT 31	30	29	28	27	26	25	24	23	22	21	20	19	18	17	BIT 16
FFFF_FFF0															
Reserved															
BIT 15	14	13	12	11	10	9	8	7	6	5	4	3	2	1	BIT 0
VERSION				TF	R/F	PART NUMBER						1	1	1	
R-K				R-K	R-K	R-K						R-1	R-1	R-1	

LEGEND:

For bits 3–15: R = Read only, -K = Value constant after RST

For bits 0–2: R = Read only, -1 = Value after RST

Bits 31:16 **Reserved.** Reads are undefined and writes have no effect.

Bits 15:12 **VERSION.** Silicon version (revision) bits

These bits identify what version of silicon the device is. Initial device version numbers start at "0000" ("0000" is the revision for the VF55BA silicon version 1.0 device).

Bit 11 **TF.** Technology Family (TF) bit

This bit distinguishes the technology family core power supply:

0 = 3.3 V for F10/C10 devices

1 = 1.8 V for F05/C05 devices

Bit 10 **R/F.** ROM/Flash bit

This bit distinguishes between ROM and Flash devices:

0 = Flash device

1 = ROM device

Bits 9:3 **PART NUMBER.** Device-specific part number bits

These bits identify the assigned device-specific part number.

The assigned device-specific part number for the VF55BA device is: 0001111.

Bits 2:0 **"1" Mandatory High.** Bits 2,1, and 0 are tied high by default.



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device part numbers

Table 9 lists all the available TMS470R1VF55BA devices.

Table 9. Device Part Number

DEVICE PART NUMBER	PROGRAM MEMORY		PACKAGE TYPE	TEMPERATURE RANGES		
	ROM	FLASH EEPROM	144-PIN LQFP	–40°C TO 85°C	–40°C TO 105°C	–40°C TO 125°C
TMS470R1VF55BAPGEA		X	X	X		
TMS470R1VF55BAPGET		X	X		X	
TMS470R1VF55BAPGEQ		X	X			X
TMS470R1VF55BBPGEA		X	X	X		
TMS470R1VF55BBPGET		X	X		X	
TMS470R1VF55BBPGEQ		X	X			X
TMS470R1VF55BEPGEA		X	X	X		
TMS470R1VF55BEPGET		X	X		X	
TMS470R1VF55BEPGEQ		X	X			X

† The various part numbers listed in this table differ due to differences in either electrical specifications or functional errata. Electrical differences will be noted in this datasheet. For functional errata, see the errata document for the specific part number you are using.

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DEVICE ELECTRICAL SPECIFICATIONS AND TIMING PARAMETERS

absolute maximum ratings over operating free-air temperature range, Q version

(unless otherwise noted)[†]

Supply voltage range, V_{CC} (see Note 1)	–0.3 V to 2.5 V
Supply voltage range: V_{CCIO} , V_{CCAD} , V_{CCP} (Flash pump) (see Note 1)	–0.3 V to 4.1V
Input voltage range: All input pins	–0.3 V to 4.1 V
Input clamp current: I_{IK} ($V_I < 0$ or $V_I > V_{CCIO}$)	
All pins except $ADIN[0:15]$, $\overline{PORRST}$, $\overline{TRST}$, $TEST$, and TCK	± 20 mA
I_{IK} ($V_I < 0$ or $V_I > V_{CCAD}$)	
$ADIN[0:15]$	± 10 mA
Operating free-air temperature ranges, T_A : A version	–40°C to 85°C
T version	–40°C to 105°C
Q version	–40°C to 125°C
Operating junction temperature range, T_J	–40°C to 150°C
Storage temperature range, T_{stg}	–65°C to 150°C

[†] Stresses beyond those listed under “absolute maximum ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTE 1: All voltage values are with respect to their associated grounds.

device recommended operating conditions[‡]

		MIN	NOM	MAX	UNIT
V_{CC}	Digital logic supply voltage (Core)	1.81		2.05	V
V_{CCIO}	Digital logic supply voltage (I/O)	3	3.3	3.6	V
V_{CCAD}	MibADC supply voltage	3	3.3	3.6	V
V_{CCP}	Flash pump supply voltage	3	3.3	3.6	V
V_{SS}	Digital logic supply ground		0		V
V_{SSAD}	MibADC supply ground	– 0.1		0.1	V
T_A	Operating free-air temperature	A version		85	°C
		T version		105	°C
		Q version		125	°C
T_J	Operating junction temperature	– 40		150	°C

[‡] All voltages are with respect to V_{SS} , except V_{CCAD} , which is with respect to V_{SSAD} .

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electrical characteristics over recommended operating free-air temperature range, Q version (unless otherwise noted)[†]

PARAMETER			TEST CONDITIONS	MIN	MAX	UNIT
V _{hys}	Input hysteresis			0.15		V
V _{IL}	Low-level input voltage	All inputs [‡] except OSCIN		– 0.3	0.8	V
		OSCIN only		– 0.3	0.35 V _{CC}	
V _{IH}	High-level input voltage	All inputs except OSCIN		2	V _{CCIO} + 0.3	V
		OSCIN only		0.65 V _{CC}	V _{CC} + 0.3	
V _{th}	Input threshold voltage	AWD only		1.35	1.8	V
RDS _{ON}	Drain to source on resistance	AWD only [§]	V _{OL} = 0.35V @ I _{OL} = 2mA	175		Ω
V _{OL}	Low-level output voltage [¶]		I _{OL} = I _{OL} MAX	0.2 V _{CCIO}		V
			I _{OL} = 50 μA	0.2		
V _{OH}	High-level output voltage [¶]		I _{OH} = I _{OH} MIN	0.8 V _{CCIO}		V
			I _{OH} = 50 μA	V _{CCIO} – 0.2		
I _{IC}	Input clamp current (I/O pins) [#]		V _I < V _{SSIO} – 0.3 or V _I > V _{CCIO} + 0.3	–2	2	mA
I _I	Input current (I/O pins)	I _{IL} Pulldown	V _I = V _{SS}	–1	1	μA
		I _{IH} Pulldown	V _I = V _{CCIO}	5	40	
		I _{IL} Pullup	V _I = V _{SS}	–40	–5	
		I _{IH} Pullup	V _I = V _{CCIO}	–1	1	
		All other pins	No pullup or pulldown	–1	1	
I _{OL}	Low-level output current	CLKOUT, TDO	V _{OL} = V _{OL} MAX	8		mA
		R _{ST} , SPInCLK, SPInSOMI, SPInSIMO		4		
		All other output pins [☆]		2		
I _{OH}	High-level output current	CLKOUT, TDO	V _{OH} = V _{OH} MIN	–8		mA
		R _{ST} , SPInCLK, SPInSOMI, SPInSIMO		–4		
		All other output pins except R _{ST} [☆]		–2		

[†] Source currents (out of the device) are negative while sink currents (into the device) are positive.

[‡] This does not apply to the PORRST pin. For PORRST exceptions, see the RST and PORRST timings section on page 34.

[§] These values help to determine the external RC network circuit. For more details, see the *TMS470R1x System Module Reference Guide* (literature number SPNU189).

[¶] V_{OL} and V_{OH} are linear with respect to the amount of load current (I_{OL}/I_{OH}) applied.

[#] Parameter does not apply to input-only or output-only pins.

^{||} n = 1 – 5.

[☆] The 2 mA buffers on this device are called zero-dominant buffers. If two of these buffers are shorted together and one is outputting a low level and the other is outputting a high level, the resulting value will always be low.

□ For Flash banks/pumps in sleep mode.

◇ I/O pins configured as inputs or outputs with no load. All pulldown inputs ≤ 0.2 V. All pullup inputs ≥ V_{CCIO} – 0.2 V.

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electrical characteristics over recommended operating free-air temperature range, Q version (unless otherwise noted)[†] (continued)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
I_{CC}	V_{CC} Digital supply current (operating mode)	SYSCLK = 60 MHz, ICLK = 20 MHz, $V_{CC} = 2.05$ V			135	mA
		SYSCLK = 24 MHz, ICLK = 12 MHz, $V_{CC} = 2.05$ V			105	mA
	V_{CC} Digital supply current (standby mode) [□]	OSCIN = 6 MHz, $V_{CC} = 2.05$ V			4.0	mA
	V_{CC} Digital supply current (halt mode) [□]	All frequencies, $V_{CC} = 2.05$ V			2.0	mA
I_{CCIO}	V_{CCIO} Digital supply current (operating mode)	No DC load, $V_{CCIO} = 3.6$ V [◇]			10	mA
	V_{CCIO} Digital supply current (standby mode)	No DC load, $V_{CCIO} = 3.6$ V [◇]			300	μA
	V_{CCIO} Digital supply current (halt mode)	No DC load, $V_{CCIO} = 3.6$ V [◇]			300	μA
I_{CCAD}	V_{CCAD} supply current (operating mode)	All frequencies, $V_{CCAD} = 3.6$ V			15	mA
	V_{CCAD} supply current (standby mode)	All frequencies, $V_{CCAD} = 3.6$ V			20	μA
	V_{CCAD} supply current (halt mode)	All frequencies, $V_{CCAD} = 3.6$ V			20	μA
I_{CCP}	V_{CCP} pump supply current	$V_{CCP} = 3.6$ V read operation			55	mA
		$V_{CCP} = 3.6$ V program and erase			70	mA
		$V_{CCP} = 3.6$ V standby mode operation [□]			20	μA
		$V_{CCP} = 3.6$ V halt mode operation [□]			20	μA
C_I	Input capacitance			2		pF
C_O	Output capacitance			3		pF

[†] Source currents (out of the device) are negative while sink currents (into the device) are positive.

[‡] This does not apply to the PORRST pin. For PORRST exceptions, see the RST and PORRST timings section on page 34.

[§] These values help to determine the external RC network circuit. For more details, see the *TMS470R1x System Module Reference Guide* (literature number SPNU189).

[¶] V_{OL} and V_{OH} are linear with respect to the amount of load current (I_{OL}/I_{OH}) applied.

[#] Parameter does not apply to input-only or output-only pins.

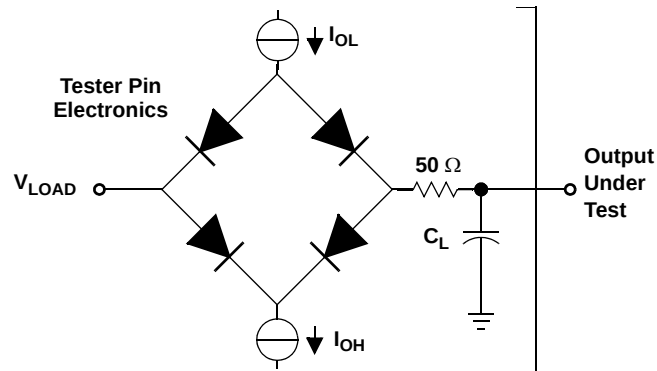
^{||} $n = 1 - 5$.

[☆] The 2 mA buffers on this device are called zero-dominant buffers. If two of these buffers are shorted together and one is outputting a low level and the other is outputting a high level, the resulting value will always be low.

[□] For Flash banks/pumps in sleep mode.

[◇] I/O pins configured as inputs or outputs with no load. All pulldown inputs ≤ 0.2 V. All pullup inputs $\geq V_{CCIO} - 0.2$ V.

PARAMETER MEASUREMENT INFORMATION



Where: I_{OL} = I_{OL} MAX for the respective pin (see Note A)
 I_{OH} = I_{OH} MIN for the respective pin (see Note A)
 V_{LOAD} = 1.5 V
 C_L = 150-pF typical load-circuit capacitance (see Note B)

NOTES: A. For these values, see the electrical characteristics over recommended operating free-air temperature range table.
B. All timing parameters measured using an external load capacitance of 150 pF unless otherwise noted.

Figure 3. Test Load Circuit

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timing parameter symbology

Timing parameter symbols have been created in accordance with JEDEC Standard 100. In order to shorten the symbols, some of the pin names and other related terminology have been abbreviated as follows:

CM	Compaction, CMPCT	RD	Read
CO	CLKOUT	RST	Reset, $\overline{\text{RST}}$
ER	Erase	RX	SCInRX
ICLK	Interface clock	S	Slave mode
M	Master mode	SCC	SCInCLK
OSC, OSCI	OSCIN	SIMO	SPInSIMO
OSCO	OSCOOUT	SOMI	SPInSOMI
P	Program, PROG	SPC	SPInCLK
R	Ready	SYS	System clock
R0	Read margin 0, RDMRGN0	TX	SCInTX
R1	Read margin 1, RDMRGN1		

Lowercase subscripts and their meanings are:

a	access time	r	rise time
c	cycle time (period)	su	setup time
d	delay time	t	transition time
f	fall time	v	valid time
h	hold time	w	pulse duration (width)

The following additional letters are used with these meanings:

H	High	X	Unknown, changing, or don't care level
L	Low	Z	High impedance
V	Valid		

The oscillator is enabled by connecting the appropriate fundamental 4–20 MHz resonator/crystal and load capacitors across the external OSCIN and OSCOUT pins as shown in Figure 4a. The oscillator is a single-stage inverter held in bias by an integrated bias resistor. This resistor is disabled during leakage test measurement and HALT mode. **TI strongly encourages each customer to submit samples of the device to the resonator/crystal vendors for validation.** The vendors are equipped to determine what load capacitors will best tune their resonator/crystal to the microcontroller device for optimum start-up and operation over temperature/voltage extremes.

Figure 1 shows two oscillator circuit options. Option (a) is an internal oscillator circuit featuring a crystal connected between OSCIN and OSCOUT, with capacitors C1 and C2 to ground. Option (b) is an external clock signal circuit where an external clock signal (0-1.8 V) is applied to OSCIN, and OSCOUT is connected to ground.

Figure 4. Recommended Crystal/Clock Connection

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ZPLL and clock specifications

timing requirements for ZPLL circuits enabled or disabled

		MIN	MAX	UNIT
$f_{(OSC)}$	Input clock frequency	4	20	MHz
$t_{c(OSC)}$	Cycle time, OSCIN	50		ns
$t_{w(OSCIL)}$	Pulse duration, OSCIN low	15		ns
$t_{w(OSCIH)}$	Pulse duration, OSCIN high	15		ns
$f_{(OSCRST)}$	OSC FAIL frequency [†]		53	kHz

[†] Causes a device reset (specifically a clock reset) by setting the RST OSC FAIL bit (GLBCTRL.15) and the OSC FAIL flag bit (GLBSTAT.1). For more detailed information on these bits and device resets, see the *TMS470R1x System Module Reference Guide* (literature number SPNU189).

switching characteristics over recommended operating conditions for clocks^{‡§}

PARAMETER		TEST CONDITIONS [¶]	MIN	MAX	UNIT
$f_{(SYS)}$	System clock frequency [#]	Pipeline mode enabled		60	MHz
		Pipeline mode disabled		24	MHz
$f_{(CONFIG)}$	System clock frequency	Flash config mode		24	MHz
$f_{(ICLK)}$	Interface clock frequency	Pipeline mode enabled		25	MHz
		Pipeline mode disabled		24	MHz
$f_{(ECLK)}$	External clock output frequency for ECP Module	Pipeline mode enabled		25	MHz
		Pipeline mode disabled		24	MHz
$t_{c(SYS)}$	Cycle time, system clock	Pipeline mode enabled	16.7		ns
		Pipeline mode disabled	41.6		ns
$t_{c(CONFIG)}$	Cycle time, system clock	Flash config mode	41.6		ns
$t_{c(ICLK)}$	Cycle time, interface clock	Pipeline mode enabled	40		ns
		Pipeline mode disabled	41.6		ns
$t_{c(ECLK)}$	Cycle time, ECP module external clock output	Pipeline mode enabled	40		ns
		Pipeline mode disabled	41.6		ns

[‡] When PLLDIS = 0, $f_{(SYS)} = M \times f_{(OSC)} / R$, where $M = \{4 \text{ or } 8\}$, $R = \{1, 2, 3, 4, 5, 6, 7, 8\}$. R is the system-clock divider determined by the CLKDIVPRE [2:0] bits in the global control register (GLBCTRL.[2:0]) and M is the PLL multiplier determined by the MULT4 bit (GLBCTRL.3).

When PLLDIS = 1, $f_{(SYS)} = f_{(OSC)} / R$, where $R = \{1, 2, 3, 4, 5, 6, 7, 8\}$.

$f_{(ICLK)} = f_{(SYS)} / X$, where $X = \{1, 2, 3, 4, 5, 6, 7, 8, 9, 10, 11, 12, 13, 14, 15, 16\}$. X is the interface clock divider ratio determined by the PCR0.[4:1] bits in the SYS module.

[§] $f_{(ECLK)} = f_{(ICLK)} / N$, where $N = \{1 \text{ to } 256\}$. N is the ECP prescale value defined by the ECPCTRL.[7:0] register bits in the ECP module.

[¶] Pipeline mode enabled or disabled is determined by the ENPIPE bit (FMREGOPT.0).

[#] Flash Vread must be set to 5V to achieve maximum System Clock Frequency.



ZPLL and clock specifications (continued)

switching characteristics over recommended operating conditions for external clocks
(see Figure 5 and Figure 6)^{†‡§}

NO.		PARAMETER	TEST CONDITIONS	MIN	MAX	UNIT
1	$t_{w(COL)}$	Pulse duration, CLKOUT low	SYSCLK or MCLK [¶]	$0.5t_{c(SYS)} - t_f$		ns
			ICLK, X is even or 1 [#]	$0.5t_{c(ICLK)} - t_f$		
			ICLK, X is odd and not 1 [#]	$0.5t_{c(ICLK)} + 0.5t_{c(SYS)} - t_f$		
2	$t_{w(COH)}$	Pulse duration, CLKOUT high	SYSCLK or MCLK [¶]	$0.5t_{c(SYS)} - t_r$		ns
			ICLK, X is even or 1 [#]	$0.5t_{c(ICLK)} - t_r$		
			ICLK, X is odd and not 1 [#]	$0.5t_{c(ICLK)} - 0.5t_{c(SYS)} - t_r$		
3	$t_{w(EOL)}$	Pulse duration, ECLK low	N is even and X is even or odd	$0.5t_{c(ECLK)} - t_f$		ns
			N is odd and X is even	$0.5t_{c(ECLK)} - t_f$		
			N is odd and X is odd and not 1	$0.5t_{c(ECLK)} + 0.5t_{c(SYS)} - t_f$		
4	$t_{w(EOH)}$	Pulse duration, ECLK high	N is even and X is even or odd	$0.5t_{c(ECLK)} - t_r$		ns
			N is odd and X is even	$0.5t_{c(ECLK)} - t_r$		
			N is odd and X is odd and not 1	$0.5t_{c(ECLK)} - 0.5t_{c(SYS)} - t_r$		

[†] X = {1,2,3,4,5,6,7,8,9,10,11,12,13,14,15,16}. X is the interface clock divider ratio determined by the PCR0.[4:1] bits in the SYS module.

[‡] N = {1 to 256}. N is the ECP prescale value defined by the ECPCTRL.[7:0] register bits in the ECP module.

[§] CLKOUT/ECLK pulse durations (low/high) are a function of the OSCIN pulse durations when PLLDIS is active.

[¶] Clock source bits selected as either SYSCLK (CLKCNTL.[6:5] = 11 binary) or MCLK (CLKCNTL.[6:5] = 10 binary).

[#] Clock source bits selected as ICLK (CLKCNTL.[6:5] = 01 binary).

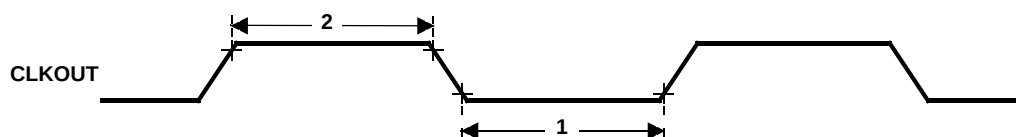


Figure 5. CLKOUT Timing Diagram

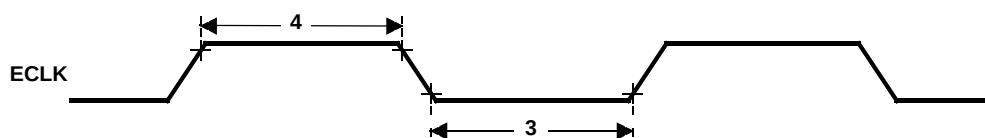


Figure 6. ECLK Timing Diagram

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RST and PORRST timings

timing requirements for $\overline{\text{PORRST}}^\dagger$ (see Figure 7)

NO.		MIN	MAX	UNIT
	V_{CCPORL}	V_{CC} low supply level when $\overline{\text{PORRST}}$ must be active during power up		0.6 V
	V_{CCPORH}	V_{CC} high supply level when $\overline{\text{PORRST}}$ must remain active during power up and become active during power down		1.5 V
	V_{CCIOPORL}	V_{CCIO} low supply level when $\overline{\text{PORRST}}$ must be active during power up		1.1 V
	V_{CCIOPORH}	V_{CCIO} high supply level when $\overline{\text{PORRST}}$ must remain active during power up and become active during power down		2.75 V
	V_{IL}	Low-level input voltage after $V_{\text{CCIO}} > V_{\text{CCIOPORH}}$		$0.2 V_{\text{CCIO}}$ V
	$V_{\text{IL(PORRST)}}$	Low-level input voltage of $\overline{\text{PORRST}}$ before $V_{\text{CCIO}} > V_{\text{CCIOPORL}}$		0.5 V
3	$t_{\text{su(PORRST)r}}$	Setup time, $\overline{\text{PORRST}}$ active before $V_{\text{CCIO}} > V_{\text{CCIOPORL}}$ during power up		0 ms
5	$t_{\text{su(VCCIO)r}}$	Setup time, $V_{\text{CCIO}} > V_{\text{CCIOPORL}}$ before $V_{\text{CC}} > V_{\text{CCPORL}}$		0 ms
6	$t_{\text{h(PORRST)r}}$	Hold time, $\overline{\text{PORRST}}$ active after $V_{\text{CC}} > V_{\text{CCPORH}}$		1 ms
7	$t_{\text{su(PORRST)f}}$	Setup time, $\overline{\text{PORRST}}$ active before $V_{\text{CC}} \leq V_{\text{CCPORH}}$ during power down		8 μs
8	$t_{\text{h(PORRST)rio}}$	Hold time, $\overline{\text{PORRST}}$ active after $V_{\text{CC}} > V_{\text{CCIOPORH}}$		1 ms
9	$t_{\text{h(PORRST)d}}$	Hold time, $\overline{\text{PORRST}}$ active after $V_{\text{CC}} < V_{\text{CCPORL}}$		0 ms
10	$t_{\text{su(PORRST)fio}}$	Setup time, $\overline{\text{PORRST}}$ active before $V_{\text{CC}} \leq V_{\text{CCIOPORH}}$ during power down		0 ns
11	$t_{\text{su(VCCIO)f}}$	Setup time, $V_{\text{CC}} < V_{\text{CCPORL}}$ before $V_{\text{CCIO}} < V_{\text{CCIOPORL}}$		0 ns

† When the V_{CC} timing requirements for $\overline{\text{PORRST}}$ are satisfied, there are no timing requirements for V_{CCP} .

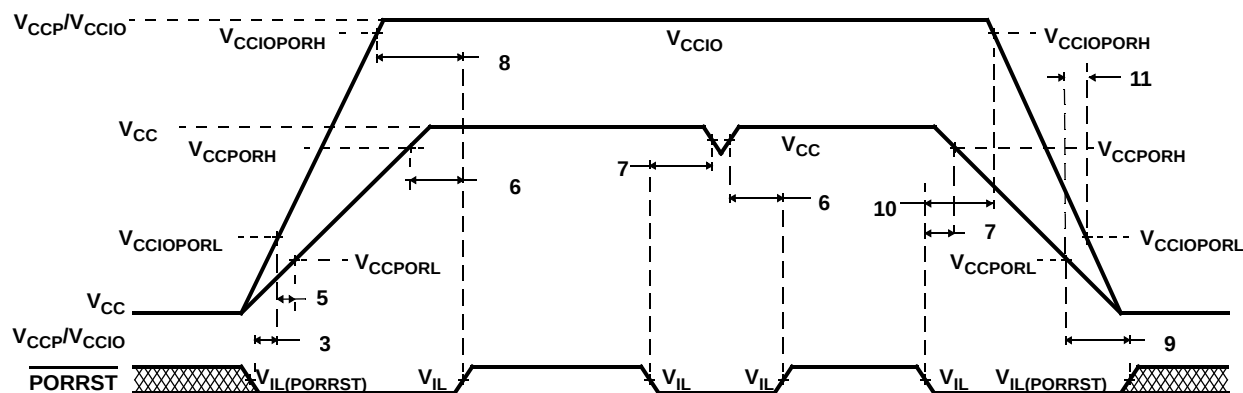


Figure 7. $\overline{\text{PORRST}}$ Timing Diagram

switching characteristics over recommended operating conditions for $\overline{\text{RST}}^\ddagger$

PARAMETER		MIN	MAX	UNIT
t _{V(RST)}	Valid time, $\overline{\text{RST}}$ active after $\overline{\text{PORRST}}$ inactive	4112t _{c(OSC)}		ns
	Valid time, $\overline{\text{RST}}$ active (all others)	8t _{c(SYS)}		

‡ Specified values do NOT include rise/fall times. For rise and fall timings, see the switching characteristics for output timings versus load capacitance table.

JTAG scan interface timing (JTAG clock specification 10-MHz and 50-pF load on TDO output)

NO.			MIN	MAX	UNIT
1	$t_{c(JTAG)}$	Cycle time, JTAG low and high period	50		ns
2	$t_{su}(TDI/TMS - TCKr)$	Setup time, TDI, TMS before TCK rise (TCKr)	15		ns
3	$t_h(TCKr - TDI/TMS)$	Hold time, TDI, TMS after TCKr	15		ns
4	$t_h(TCKf - TDO)$	Hold time, TDO after TCKf	10		ns
5	$t_d(TCKf - TDO)$	Delay time, TDO valid after TCK fall (TCKf)		45	ns

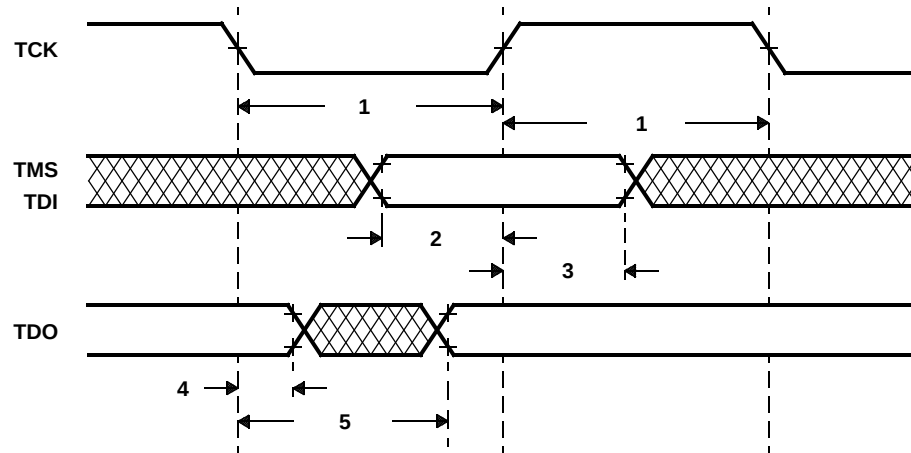


Figure 8. JTAG Scan Timing

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output timings

switching characteristics for output timings versus load capacitance (C_L) (see Figure 9)

PARAMETER			MIN	MAX	UNIT
t_r	Rise time, CLKOUT, AWD, TDO	$C_L = 15 \text{ pF}$	0.5	2.50	ns
		$C_L = 50 \text{ pF}$	1.5	5	
		$C_L = 100 \text{ pF}$	3	9	
		$C_L = 150 \text{ pF}$	4.5	12.5	
t_f	Fall time, CLKOUT, AWD, TDO	$C_L = 15 \text{ pF}$	0.5	2.5	ns
		$C_L = 50 \text{ pF}$	1.5	5	
		$C_L = 100 \text{ pF}$	3	9	
		$C_L = 150 \text{ pF}$	4.5	12.5	
t_r	Rise time, SPInCLK, SPInSOMI, SPInSIMO [†]	$C_L = 15 \text{ pF}$	2.5	8	ns
		$C_L = 50 \text{ pF}$	5	14	
		$C_L = 100 \text{ pF}$	9	23	
		$C_L = 150 \text{ pF}$	13	32	
t_f	Fall time, $\overline{\text{RST}}$, SPInCLK, SPInSOMI, SPInSIMO [†]	$C_L = 15 \text{ pF}$	2.5	8	ns
		$C_L = 50 \text{ pF}$	5	14	
		$C_L = 100 \text{ pF}$	9	23	
		$C_L = 150 \text{ pF}$	13	32	
t_r	Rise time, all other output pins	$C_L = 15 \text{ pF}$	2.5	12	ns
		$C_L = 50 \text{ pF}$	6.0	28	
		$C_L = 100 \text{ pF}$	12	50	
		$C_L = 150 \text{ pF}$	18	73	
t_f	Fall time, all other output pins	$C_L = 15 \text{ pF}$	3	12	ns
		$C_L = 50 \text{ pF}$	8.5	28	
		$C_L = 100 \text{ pF}$	16	50	
		$C_L = 150 \text{ pF}$	23	73	

[†] n = 1 – 5

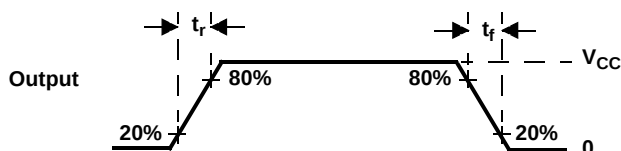


Figure 9. CMOS-Level Outputs

input timings

timing requirements for input timings[†] (see Figure 10)

		MIN	MAX	UNIT
t _{pw}	Input minimum pulse width	t _{c(ICLK)} + 10		ns

[†] t_{c(ICLK)} = interface clock cycle time = 1/f_(ICLK)

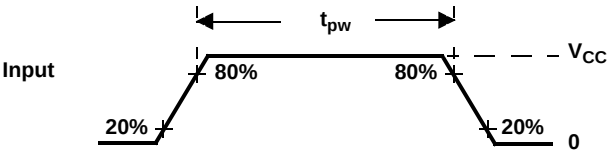


Figure 10. CMOS-Level Inputs

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Flash timings

timing requirements for program Flash[†]

		MIN	TYP	MAX	UNIT
t _{prog} (16-bit)	Half word (16-bit) programming time	4	16	200	μs
t _{prog} (Total)	768K-byte programming time [‡]		6	20	s
t _{erase} (sector)	Sector erase time		2	15	s
t _{wec}	Write/erase cycles at T _A = 125°C			100	cycles

[†] For more detailed information on the Flash core sectors, see the *Flash program and erase* section of this data sheet.

[‡] The 768K-byte programming times include overhead of state machine.

SPIn master mode timing parameters

SPIn master mode external timing parameters (CLOCK PHASE = 0, SPInCLK = output, SPInSIMO = output, and SPInSOMI = input)^{†‡§} (see Figure 11)

NO.		MIN	MAX	UNIT
1	$t_{c(SPC)M}$ Cycle time, SPInCLK [¶]	100	$256t_{c(ICLK)}$	ns
2 [#]	$t_{w(SPCH)M}$ Pulse duration, SPInCLK high (clock polarity = 0)	$0.5t_{c(SPC)M} - t_f$	$0.5t_{c(SPC)M} + 5$	ns
	$t_{w(SPCL)M}$ Pulse duration, SPInCLK low (clock polarity = 1)	$0.5t_{c(SPC)M} - t_f$	$0.5t_{c(SPC)M} + 5$	
3 [#]	$t_{w(SPCL)M}$ Pulse duration, SPInCLK low (clock polarity = 0)	$0.5t_{c(SPC)M} - t_f$	$0.5t_{c(SPC)M} + 5$	ns
	$t_{w(SPCH)M}$ Pulse duration, SPInCLK high (clock polarity = 1)	$0.5t_{c(SPC)M} - t_f$	$0.5t_{c(SPC)M} + 5$	
4 [#]	$t_{d(SPCH-SIMO)M}$ Delay time, SPInCLK high to SPInSIMO valid (clock polarity = 0)		10	ns
	$t_{d(SPCL-SIMO)M}$ Delay time, SPInCLK low to SPInSIMO valid (clock polarity = 1)		10	
5 [#]	$t_{v(SPCL-SIMO)M}$ Valid time, SPInSIMO data valid after SPInCLK low (clock polarity = 0)	$t_{c(SPC)M} - 5 - t_f$		ns
	$t_{v(SPCH-SIMO)M}$ Valid time, SPInSIMO data valid after SPInCLK high (clock polarity = 1)	$t_{c(SPC)M} - 5 - t_f$		
6 [#]	$t_{su(SOMI-SPCL)M}$ Setup time, SPInSOMI before SPInCLK low (clock polarity = 0)	6		ns
	$t_{su(SOMI-SPCH)M}$ Setup time, SPInSOMI before SPInCLK high (clock polarity = 1)	6		
7 [#]	$t_{v(SPCL-SOMI)M}$ Valid time, SPInSOMI data valid after SPInCLK low (clock polarity = 0)	4		ns
	$t_{v(SPCH-SOMI)M}$ Valid time, SPInSOMI data valid after SPInCLK high (clock polarity = 1)	4		

[†] The MASTER bit (SPInCTRL2.3) is set and the CLOCK PHASE bit (SPInCTRL2.0) is cleared.

[‡] $t_{c(ICLK)}$ = interface clock cycle time = $1/f_{(ICLK)}$

[§] For rise and fall timings, see the "switching characteristics for output timings versus load capacitance" table.

[¶] When the SPI is in Master mode, the following must be true:

For PS values from 1 to 255: $t_{c(SPC)M} \geq (PS + 1)t_{c(ICLK)} \geq 100$ ns, where PS is the prescale value set in the SPInCTL1.[12:5] register bits.

For PS values of 0: $t_{c(SPC)M} = 2t_{c(ICLK)} \geq 100$ ns.

[#] The active edge of the SPInCLK signal referenced is controlled by the CLOCK POLARITY bit (SPInCTRL2.1).

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SPIn master mode timing parameters (continued)

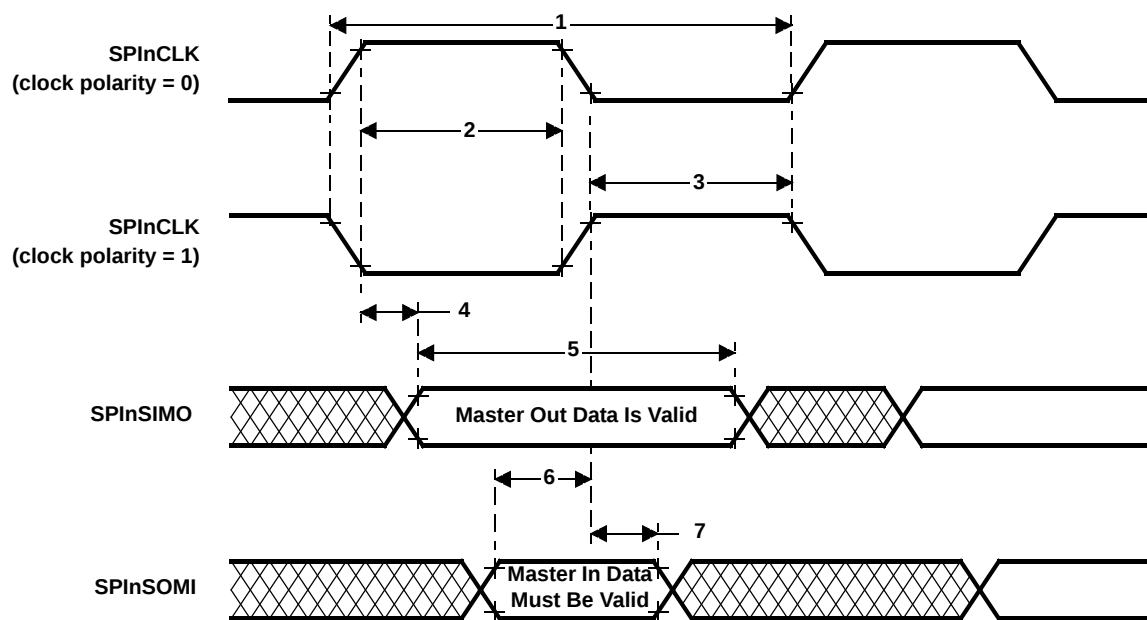


Figure 11. SPIn Master Mode External Timing (CLOCK PHASE = 0)

SPIn master mode timing parameters (continued)

SPIn master mode external timing parameters (CLOCK PHASE = 1, SPInCLK = output, SPInSIMO = output, and SPInSOMI = input)^{†‡§} (see Figure 12)

NO.			MIN	MAX	UNIT
1	t _c (SPC) _M	Cycle time, SPInCLK [¶]	100	256t _c (ICLK)	ns
2 [#]	t _w (SPCH) _M	Pulse duration, SPInCLK high (clock polarity = 0)	0.5t _c (SPC) _M – t _r	0.5t _c (SPC) _M + 5	ns
	t _w (SPCL) _M	Pulse duration, SPInCLK low (clock polarity = 1)	0.5t _c (SPC) _M – t _f	0.5t _c (SPC) _M + 5	
3 [#]	t _w (SPCL) _M	Pulse duration, SPInCLK low (clock polarity = 0)	0.5t _c (SPC) _M – t _f	0.5t _c (SPC) _M + 5	ns
	t _w (SPCH) _M	Pulse duration, SPInCLK high (clock polarity = 1)	0.5t _c (SPC) _M – t _r	0.5t _c (SPC) _M + 5	
4 [#]	t _v (SIMO-SPCH) _M	Valid time, SPInCLK high after SPInSIMO data valid (clock polarity = 0)	0.5t _c (SPC) _M – 15		ns
	t _v (SIMO-SPCL) _M	Valid time, SPInCLK low after SPInSIMO data valid (clock polarity = 1)	0.5t _c (SPC) _M – 15		
5 [#]	t _v (SPCH-SIMO) _M	Valid time, SPInSIMO data valid after SPInCLK high (clock polarity = 0)	0.5t _c (SPC) _M – 5 – t _r		ns
	t _v (SPCL-SIMO) _M	Valid time, SPInSIMO data valid after SPInCLK low (clock polarity = 1)	0.5t _c (SPC) _M – 5 – t _f		
6 [#]	t _{su} (SOMI-SPCH) _M	Setup time, SPInSOMI before SPInCLK high (clock polarity = 0)	6		ns
	t _{su} (SOMI-SPCL) _M	Setup time, SPInSOMI before SPInCLK low (clock polarity = 1)	6		
7 [#]	t _v (SPCH-SOMI) _M	Valid time, SPInSOMI data valid after SPInCLK high (clock polarity = 0)	4		ns
	t _v (SPCL-SOMI) _M	Valid time, SPInSOMI data valid after SPInCLK low (clock polarity = 1)	4		

[†] The MASTER bit (SPInCTRL2.3) is set and the CLOCK PHASE bit (SPInCTRL2.0) is set.

[‡] $t_{c(ICK)K}$ = interface clock cycle time = $1/f_{(ICK)K}$

[§] For rise and fall timings, see the "switching characteristics for output timings versus load capacitance" table.

[¶] When the SPI is in Master mode, the following must be true:

For PS values from 1 to 255: $t_{c(SPC)M} \geq (PS + 1)t_{c(ICK)K} \geq 100$ ns, where PS is the prescale value set in the SPInCTL1.[12:5] register bits.

For PS values of 0: $t_{c(SPC)M} = 2t_{c(ICK)K} \geq 100$ ns.

[#] The active edge of the SPInCLK signal referenced is controlled by the CLOCK POLARITY bit (SPInCTRL2.1).

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SPIn master mode timing parameters (continued)

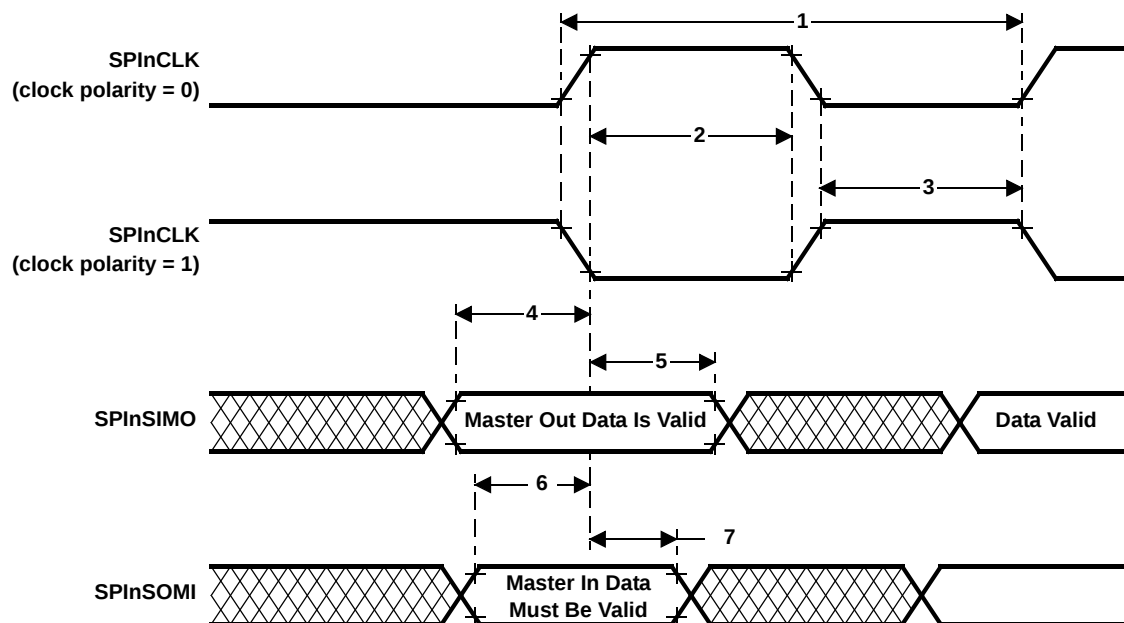


Figure 12. SPIn Master Mode External Timing (CLOCK PHASE = 1)

SPIn slave mode timing parameters

SPIn slave mode external timing parameters (CLOCK PHASE = 0, SPInCLK = input, SPInSIMO = input, and SPInSOMI = output)^{†‡§¶} (see Figure 13)

NO.			MIN	MAX	UNIT
1	$t_{c(SPC)S}$	Cycle time, SPInCLK [#]	100	$256t_{c(I)CLK}$	ns
2	$t_{w(SPCH)S}$	Pulse duration, SPInCLK high (clock polarity = 0)	$0.5t_{c(SPC)S} - 0.25t_{c(I)CLK}$	$0.5t_{c(SPC)S} + 0.25t_{c(I)CLK}$	ns
	$t_{w(SPCL)S}$	Pulse duration, SPInCLK low (clock polarity = 1)	$0.5t_{c(SPC)S} - 0.25t_{c(I)CLK}$	$0.5t_{c(SPC)S} + 0.25t_{c(I)CLK}$	
3	$t_{w(SPCL)S}$	Pulse duration, SPInCLK low (clock polarity = 0)	$0.5t_{c(SPC)S} - 0.25t_{c(I)CLK}$	$0.5t_{c(SPC)S} + 0.25t_{c(I)CLK}$	ns
	$t_{w(SPCH)S}$	Pulse duration, SPInCLK high (clock polarity = 1)	$0.5t_{c(SPC)S} - 0.25t_{c(I)CLK}$	$0.5t_{c(SPC)S} + 0.25t_{c(I)CLK}$	
4	$t_d(SPCH-SOMI)S$	Delay time, SPInCLK high to SPInSOMI valid (clock polarity = 0)		$6 + t_r$	ns
	$t_d(SPCL-SOMI)S$	Delay time, SPInCLK low to SPInSOMI valid (clock polarity = 1)		$6 + t_f$	
5	$t_v(SPCH-SOMI)S$	Valid time, SPInSOMI data valid after SPInCLK high (clock polarity = 0)	$t_{c(SPC)S} - 6 - t_r$		ns
	$t_v(SPCL-SOMI)S$	Valid time, SPInSOMI data valid after SPInCLK low (clock polarity = 1)	$t_{c(SPC)S} - 6 - t_f$		
6	$t_{su}(SIMO-SPCL)S$	Setup time, SPInSIMO before SPInCLK low (clock polarity = 0)	6		ns
	$t_{su}(SIMO-SPCH)S$	Setup time, SPInSIMO before SPInCLK high (clock polarity = 1)	6		
7	$t_v(SPCL-SIMO)S$	Valid time, SPInSIMO data valid after SPInCLK low (clock polarity = 0)	6		ns
	$t_v(SPCH-SIMO)S$	Valid time, SPInSIMO data valid after SPInCLK high (clock polarity = 1)	6		

[†] The MASTER bit (SPInCTRL2.3) is cleared and the CLOCK PHASE bit (SPInCTRL2.0) is cleared.

[‡] If the SPI is in slave mode, the following must be true: $t_{c(SPC)S} \geq (PS + 1)t_{c(I)CLK}$, where PS = prescale value set in SPInCTL1.[12:5].

[§] For rise and fall timings, see the "switching characteristics for output timings versus load capacitance" table.

[¶] $t_{c(I)CLK}$ = interface clock cycle time = $1/f_{(I)CLK}$

[#] When the SPIn is in Slave mode, the following must be true:

For PS values from 1 to 255: $t_{c(SPC)S} \geq (PS + 1)t_{c(I)CLK} \geq 100$ ns, where PS is the prescale value set in the SPInCTL1.[12:5] register bits.

For PS values of 0: $t_{c(SPC)S} = 2t_{c(I)CLK} \geq 100$ ns.

^{||} The active edge of the SPInCLK signal referenced is controlled by the CLOCK POLARITY bit (SPInCTRL2.1).

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SPIn slave mode timing parameters (continued)

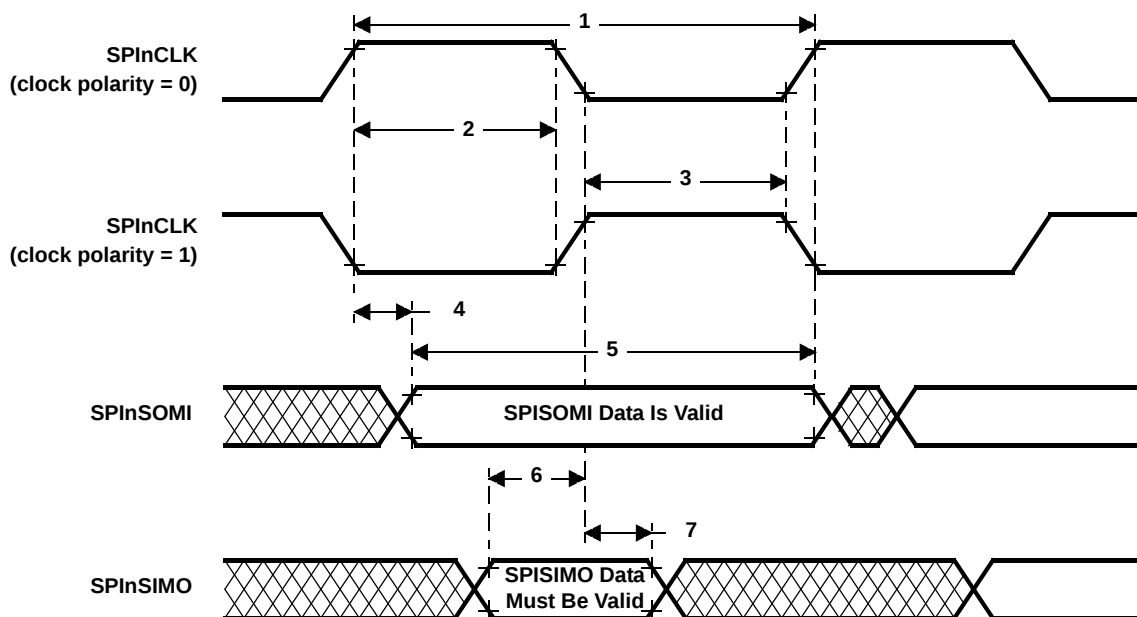


Figure 13. SPIn Slave Mode External Timing (CLOCK PHASE = 0)

SPIn slave mode timing parameters (continued)

SPIn slave mode external timing parameters (CLOCK PHASE = 1, SPInCLK = input, SPInSIMO = input, and SPInSOMI = output)^{†‡§¶} (see Figure 14)

NO.			MIN	MAX	UNIT
1	$t_{c(SPC)S}$	Cycle time, SPInCLK [#]	100	$256t_{c(I)CLK}$	ns
2	$t_{w(SPCH)S}$	Pulse duration, SPInCLK high (clock polarity = 0)	$0.5t_{c(SPC)S} - 0.25t_{c(I)CLK}$	$0.5t_{c(SPC)S} + 0.25t_{c(I)CLK}$	ns
	$t_{w(SPCL)S}$	Pulse duration, SPInCLK low (clock polarity = 1)	$0.5t_{c(SPC)S} - 0.25t_{c(I)CLK}$	$0.5t_{c(SPC)S} + 0.25t_{c(I)CLK}$	
3	$t_{w(SPCL)S}$	Pulse duration, SPInCLK low (clock polarity = 0)	$0.5t_{c(SPC)S} - 0.25t_{c(I)CLK}$	$0.5t_{c(SPC)S} + 0.25t_{c(I)CLK}$	ns
	$t_{w(SPCH)S}$	Pulse duration, SPInCLK high (clock polarity = 1)	$0.5t_{c(SPC)S} - 0.25t_{c(I)CLK}$	$0.5t_{c(SPC)S} + 0.25t_{c(I)CLK}$	
4	$t_{v(SOMI-SPCH)S}$	Valid time, SPInSOMI data valid before SPInCLK high (clock polarity = 0)	$0.5t_{c(SPC)S} - 6 - t_r$		ns
	$t_{v(SOMI-SPCL)S}$	Valid time, SPInSOMI data valid before SPInCLK low (clock polarity = 1)	$0.5t_{c(SPC)S} - 6 - t_f$		
5	$t_{v(SPCH-SOMI)S}$	Valid time, SPInSOMI data valid after SPInCLK high (clock polarity = 0)	$0.5t_{c(SPC)S} - 6 - t_r$		ns
	$t_{v(SPCL-SOMI)S}$	Valid time, SPInSOMI data valid after SPInCLK low (clock polarity = 1)	$0.5t_{c(SPC)S} - 6 - t_f$		
6	$t_{su(SIMO-SPCH)S}$	Setup time, SPInSIMO before SPInCLK high (clock polarity = 0)	6		ns
	$t_{su(SIMO-SPCL)S}$	Setup time, SPInSIMO before SPInCLK low (clock polarity = 1)	6		
7	$t_{v(SPCH-SIMO)S}$	Valid time, SPInSIMO data valid after SPInCLK high (clock polarity = 0)	6		ns
	$t_{v(SPCL-SIMO)S}$	Valid time, SPInSIMO data valid after SPInCLK low (clock polarity = 1)	6		

[†] The MASTER bit (SPInCTRL2.3) is cleared and the CLOCK PHASE bit (SPInCTRL2.0) is set.

[‡] If the SPI is in slave mode, the following must be true: $t_{c(SPC)S} \geq (PS + 1)t_{c(I)CLK}$, where PS = prescale value set in SPInCTL1.[12:5].

[§] For rise and fall timings, see the "switching characteristics for output timings versus load capacitance" table.

[¶] $t_{c(I)CLK}$ = interface clock cycle time = $1/f_{(I)CLK}$

[#] When the SPIn is in Slave mode, the following must be true:

For PS values from 1 to 255: $t_{c(SPC)S} \geq (PS + 1)t_{c(I)CLK} \geq 100$ ns, where PS is the prescale value set in the SPInCTL1.[12:5] register bits.

For PS values of 0: $t_{c(SPC)S} = 2t_{c(I)CLK} \geq 100$ ns.

^{||} The active edge of the SPInCLK signal referenced is controlled by the CLOCK POLARITY bit (SPInCTRL2.1).

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SPIn slave mode timing parameters (continued)

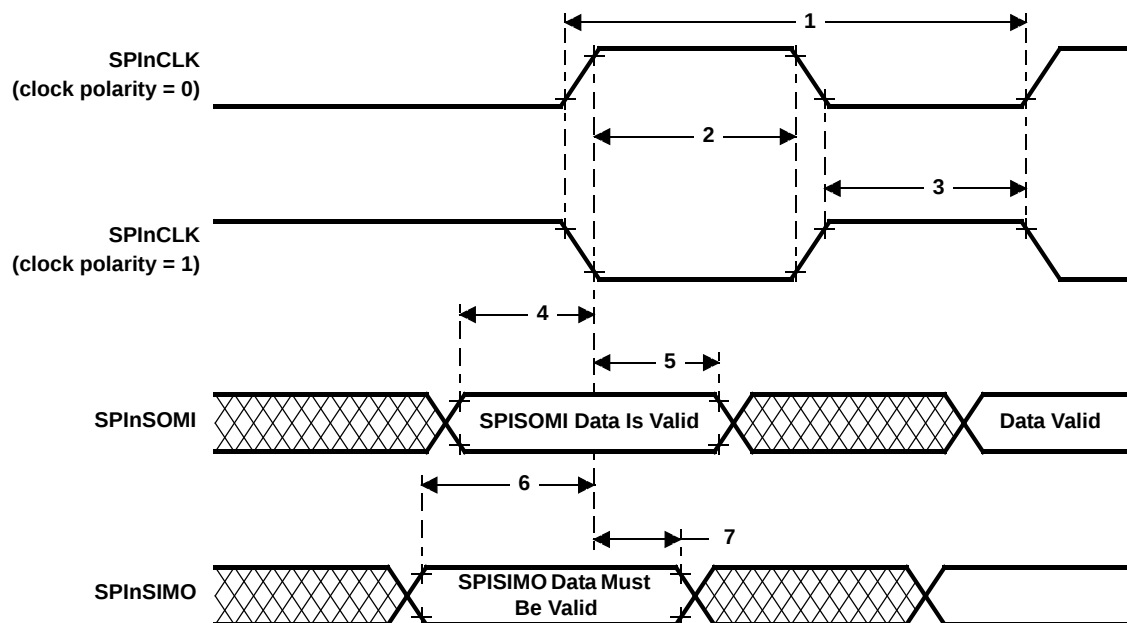


Figure 14. SPIn Slave Mode External Timing (CLOCK PHASE = 1)

SCIn isosynchronous mode timings — internal clock

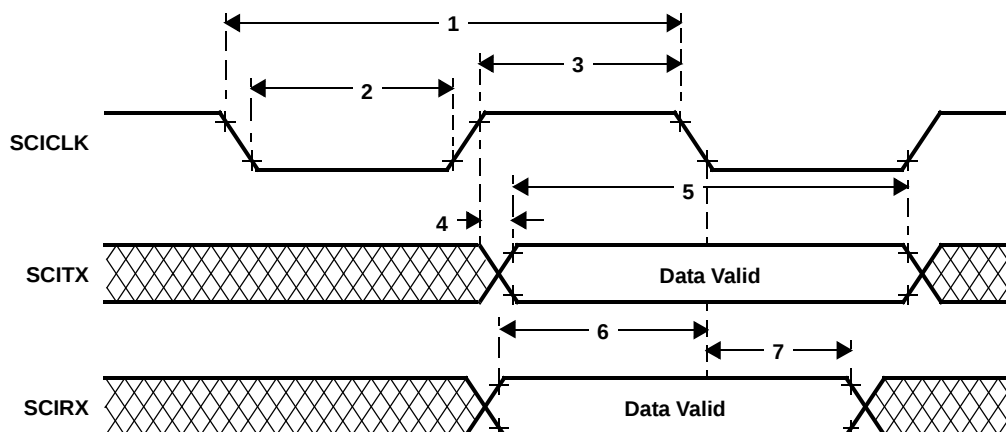
timing requirements for internal clock SCIn isosynchronous mode^{†‡§} (see Figure 15)

NO.			(BAUD + 1) IS EVEN OR BAUD = 0		(BAUD + 1) IS ODD AND BAUD ≠ 0		UNIT
			MIN	MAX	MIN	MAX	
1	$t_{c(SCC)}$	Cycle time, SCInCLK	$2t_{c(ICKL)}$	$2^{24}t_{c(ICKL)}$	$3t_{c(ICKL)}$	$(2^{24}-1)t_{c(ICKL)}$	ns
2	$t_{w(SCCL)}$	Pulse duration, SCInCLK low	$0.5t_{c(SCC)} - t_f$	$0.5t_{c(SCC)} + 5$	$0.5t_{c(SCC)} + 0.5t_{c(ICKL)} - t_f$	$0.5t_{c(SCC)} + 0.5t_{c(ICKL)}$	ns
3	$t_{w(SCCH)}$	Pulse duration, SCInCLK high	$0.5t_{c(SCC)} - t_r$	$0.5t_{c(SCC)} + 5$	$0.5t_{c(SCC)} - 0.5t_{c(ICKL)} - t_r$	$0.5t_{c(SCC)} - 0.5t_{c(ICKL)}$	ns
4	$t_{d(SCCH-TXV)}$	Delay time, SCInCLK high to SCInTX valid	10		10		ns
5	$t_{v(TX)}$	Valid time, SCInTX data after SCInCLK low	$t_{c(SCC)} - 10$		$t_{c(SCC)} - 10$		ns
6	$t_{su(RX-SCCL)}$	Setup time, SCInRX before SCInCLK low	$t_{c(ICKL)} + t_f + 20$		$t_{c(ICKL)} + t_f + 20$		ns
7	$t_{v(SCCL-RX)}$	Valid time, SCInRX data after SCInCLK low	$-t_{c(ICKL)} + t_f + 20$		$-t_{c(ICKL)} + t_f + 20$		ns

[†] BAUD = 24-bit concatenated value formed by the SCI[H,M,L]BAUD registers.

[‡] $t_{c(ICKL)}$ = interface clock cycle time = $1/f_{(ICKL)}$

[§] For rise and fall timings, see the switching characteristics for output timings versus load capacitance table.



NOTE A: Data transmission/reception characteristics for isosynchronous mode with internal clocking are similar to the asynchronous mode. Data transmission occurs on the SCICLK rising edge, and data reception on the SCICLK falling edge.

Figure 15. SCIn Isosynchronous Mode Timing Diagram for Internal Clock

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SCIn isosynchronous mode timings — external clock

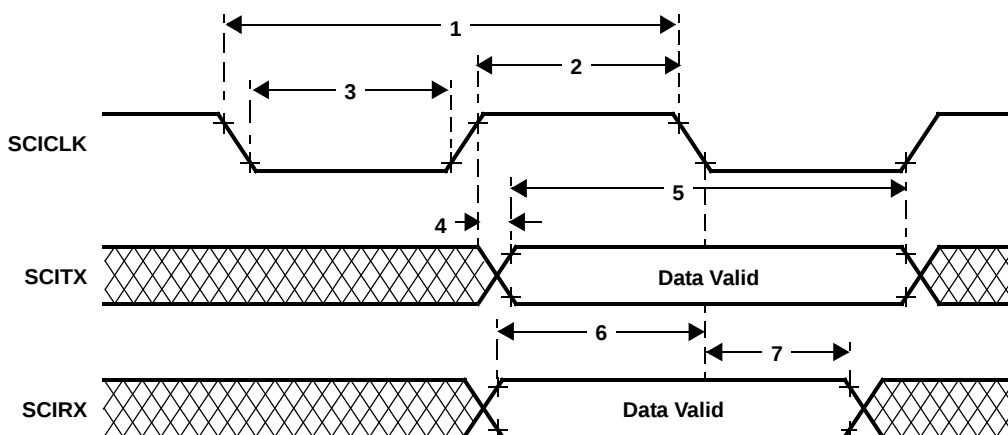
timing requirements for external clock SCIn isosynchronous mode^{†‡} (see Figure 16)

NO.		MIN	MAX	UNIT
1	$t_{c(SCC)}$ Cycle time, SCInCLK [§]	$8t_{c(ICKL)}$		ns
2	$t_{w(SCCH)}$ Pulse duration, SCInCLK high	$0.5t_{c(SCC)} - 0.25t_{c(ICKL)}$	$0.5t_{c(SCC)} + 0.25t_{c(ICKL)}$	ns
3	$t_{w(SCCL)}$ Pulse duration, SCInCLK low	$0.5t_{c(SCC)} - 0.25t_{c(ICKL)}$	$0.5t_{c(SCC)} + 0.25t_{c(ICKL)}$	ns
4	$t_{d(SCCH-TXV)}$ Delay time, SCInCLK high to SCInTX valid		$2t_{c(ICKL)} + 12 + t_f$	ns
5	$t_{v(TX)}$ Valid time, SCInTX data after SCInCLK low	$2t_{c(SCC)} - 10$		ns
6	$t_{su(RX-SCCL)}$ Setup time, SCInRX before SCInCLK low	0		ns
7	$t_{v(SCCL-RX)}$ Valid time, SCInRX data after SCInCLK low	$2t_{c(ICKL)} + 10$		ns

[†] $t_{c(ICKL)}$ = interface clock cycle time = $1/f_{(ICKL)}$

[‡] For rise and fall timings, see the switching characteristics for output timings versus load capacitance table.

[§] When driving an external SCInCLK, the following must be true: $t_{c(SCC)} \geq 8t_{c(ICKL)}$



NOTE A: Data transmission/reception characteristics for isosynchronous mode with external clocking are similar to the asynchronous mode. Data transmission occurs on the SCICLK rising edge, and data reception on the SCICLK falling edge.

Figure 16. SCIn Isosynchronous Mode Timing Diagram for External Clock

high-end timer (HET) timings

minimum PWM output pulse width:

This is equal to one High Resolution Clock Period (HRP). The HRP is defined by the 6-bit High Resolution Prescale Factor (hr) which is user defined, giving prescale factors of 1 to 64, with a linear increment of codes.

Therefore, the minimum PWM output pulse width = $HRP(\min) = hr(\min)/SYSCLK = 1/SYSCLK$

For example, for a SYSCLK of 30 MHz, the minimum PWM output pulse width = $1/30 = 33.33\text{ns}$

minimum input pulses we can capture:

The input pulse width must be greater or equal to the Low Resolution Clock Period (LRP), i.e., the HET loop (the HET program must fit within the LRP). The LRP is defined by the 3-bit Loop-Resolution Prescale Factor (lr), which is user defined, with a power of 2 increment of codes. That is, the value of lr can be 1, 2, 4, 8, 16, or 32.

Therefore, the minimum input pulse width = $LRP(\min) = hr(\min) * lr(\min)/SYSCLK = 1 * 1/SYSCLK$

For example, with a SYSCLK of 30 MHz, the minimum input pulse width = $1 * 1/30 = 33.33 \text{ ns}$

Note: Once the input pulse width is greater than LRP, the resolution of the measurement is still HRP. (That is, the captured value gives the number of HRP clocks inside the pulse.)

Abbreviations:

High resolution clock period = $HRP = hr/SYSCLK$

Loop resolution clock period = $LRP = hr*lr/SYSCLK$

hr = HET high resolution divide rate = 1, 2, 3,...63, 64

lr = HET low resolution divide rate = 1, 2, 4, 8, 16, 32

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high-end CAN controller (HECCn) mode timings

dynamic characteristics for the CANnHTX and CANnHRX pins

PARAMETER		MIN	MAX	UNIT
$t_d(\text{CANnHTX})$	Delay time, transmit shift register to CANnHTX pin [†]		15	ns
$t_d(\text{CANnHRX})$	Delay time, CANnHRX pin to receive shift register		5	ns

[†] These values do not include rise/fall times of the output buffer.

multi-buffered A-to-D converter (MibADC)

The multi-buffered A-to-D converter (MibADC) has a separate power bus for its analog circuitry that enhances the A-to-D performance by preventing digital switching noise on the logic circuitry which could be present on V_{SS} and V_{CC} from coupling into the A-to-D analog stage. All A-to-D specifications are given with respect to AD_{REFLO} unless otherwise noted.

Resolution 10 bits (1024 values)
 Monotonic Assured
 Output conversion code 00h to 3FFh [00 for $V_{AI} \leq AD_{REFLO}$; 3FF for $V_{AI} \geq AD_{REFHI}$]

MibADC recommended operating conditions[†]

		MIN	MAX	UNIT
AD_{REFHI}	A-to-D high-voltage reference source	V_{SSAD}	V_{CCAD}	V
AD_{REFLO}	A-to-D low-voltage reference source	V_{SSAD}	V_{CCAD}	V
V_{AI}	Analog input voltage	$V_{SSAD} - 0.3$	$V_{CCAD} + 0.3$	V
I_{AIC}	Analog input clamp current [‡] ($V_{AI} < V_{SSAD} - 0.3$ or $V_{AI} > V_{CCAD} + 0.3$)	- 2	2	mA

[†] For V_{CCAD} and V_{SSAD} recommended operating conditions, see the device recommended operating conditions table.

[‡] Input currents into any ADC input channel outside the specified limits could affect conversion results of other channels.

operating characteristics over full ranges of recommended operating conditions^{§¶}

PARAMETER		DESCRIPTION/CONDITIONS		MIN	TYP	MAX	UNIT
R_i	Analog input resistance	See Figure 17			250	500	Ω
C_i	Analog input capacitance	See Figure 17	Conversion			10	pF
			Sampling			30	pF
I_{AIL}	Analog input leakage current	See Figure 17		-1		1	μA
$I_{ADREFHI}$	AD_{REFHI} input current	$AD_{REFHI} = 3.6$ V, $AD_{REFLO} = V_{SSAD}$				5	mA
CR	Conversion range over which specified accuracy is maintained	$AD_{REFHI} - AD_{REFLO}$		3		3.6	V
E_{DNL}	Differential nonlinearity error	Difference between the actual step width and the ideal value. (See Figure 18)				± 1.5	LSB
E_{INL}	Integral nonlinearity error	Maximum deviation from the best straight line through the MibADC. MibADC transfer characteristics, excluding the quantization error. (See Figure 19)				± 2.0	LSB
E_{TOT}	Total error/Absolute accuracy	Maximum value of the difference between an analog value and the ideal midstep value. (See Figure 20)				± 2	LSB

[§] $V_{CCIO} = V_{CCAD} = AD_{REFHI}$

[¶] 1 LSB = $(AD_{REFHI} - AD_{REFLO})/2^{10}$ for the MibADC

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multi-buffered A-to-D converter (MibADC) (continued)

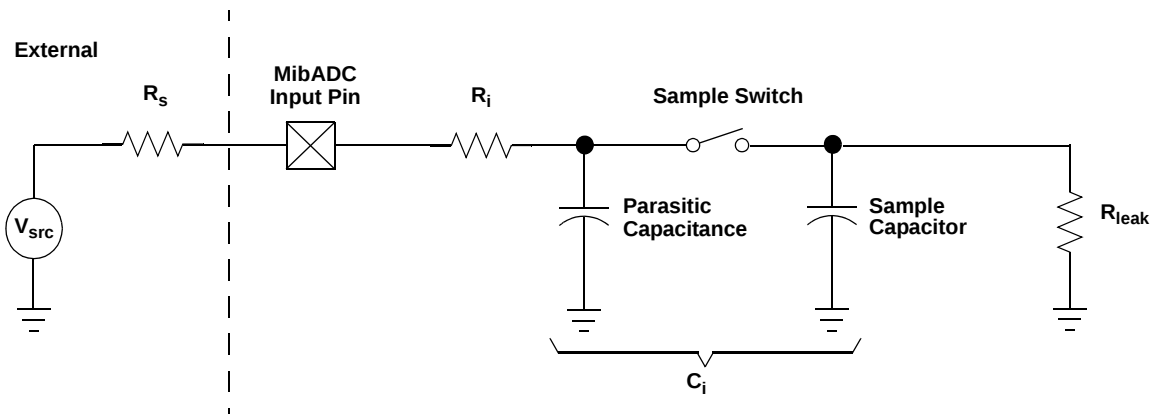


Figure 17. MibADC Input Equivalent Circuit

Multi-Buffer ADC timing requirements

		MIN	MAX	UNIT
$t_{c(ADCLK)}$	Cycle time, MibADC clock	0.05		μS
$t_{d(SH)}$	Delay time, sample and hold time	1		μS
$t_{d(C)}$	Delay time, conversion time	0.55		μS
$t_{d(SHC)}^{\dagger}$	Delay time, total sample/hold and conversion time	1.55		μS

[†] This is the minimum sample/hold and conversion time that can be achieved. These parameters are dependent on many factors for more detail, see the *TMS470R1x Multi-Buffered Analog-to-Digital Converter (MibADC) Reference Guide* (literature number SPNU206).

multi-buffered A-to-D converter (MibADC) (continued)

The differential nonlinearity error shown in Figure 18 (sometimes referred to as differential linearity) is the difference between an actual step width and the ideal value of 1 LSB.

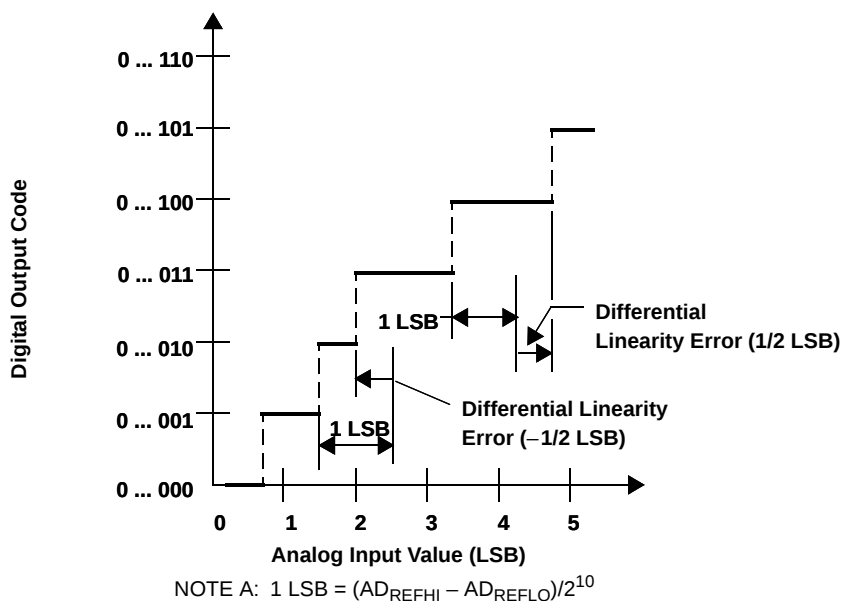


Figure 18. Differential Nonlinearity (DNL)

The integral nonlinearity error shown in Figure 19 (sometimes referred to as linearity error) is the deviation of the values on the actual transfer function from a straight line.

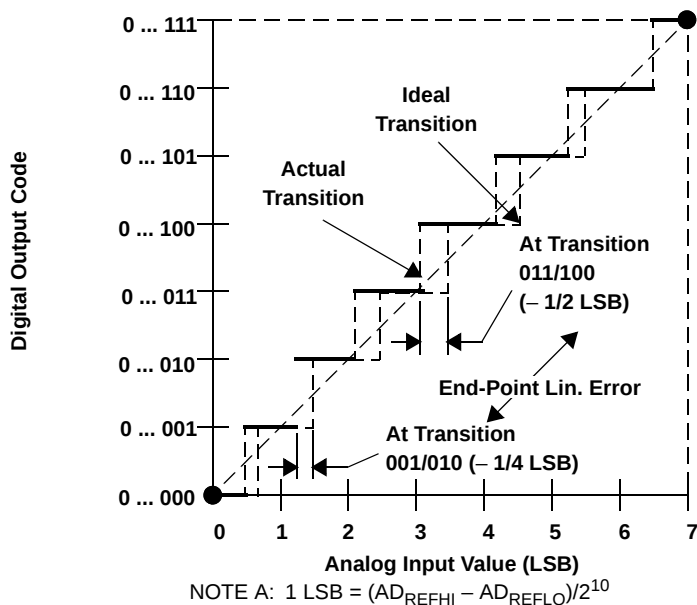


Figure 19. Integral Nonlinearity (INL) Error

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multi-buffer A-to-D converter (MibADC) (continued)

The absolute accuracy or total error of an MibADC as shown in Figure 20 is the maximum value of the difference between an analog value and the ideal midstep value.

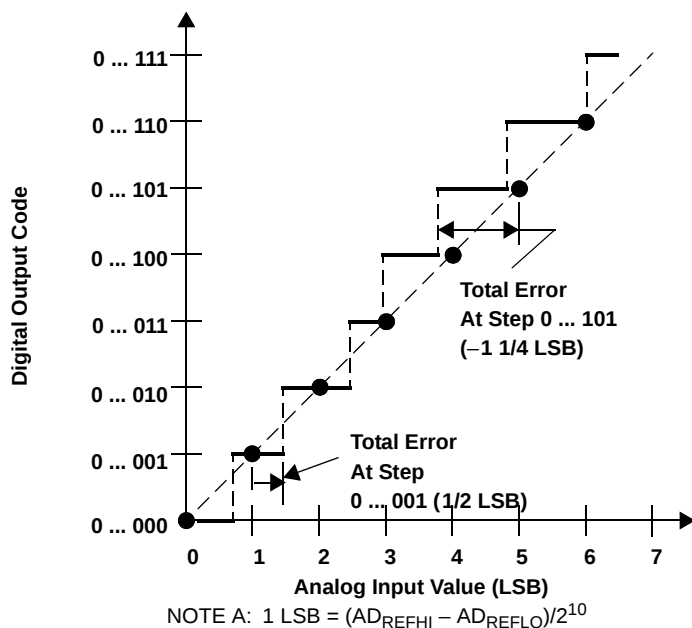


Figure 20. Absolute Accuracy (Total) Error

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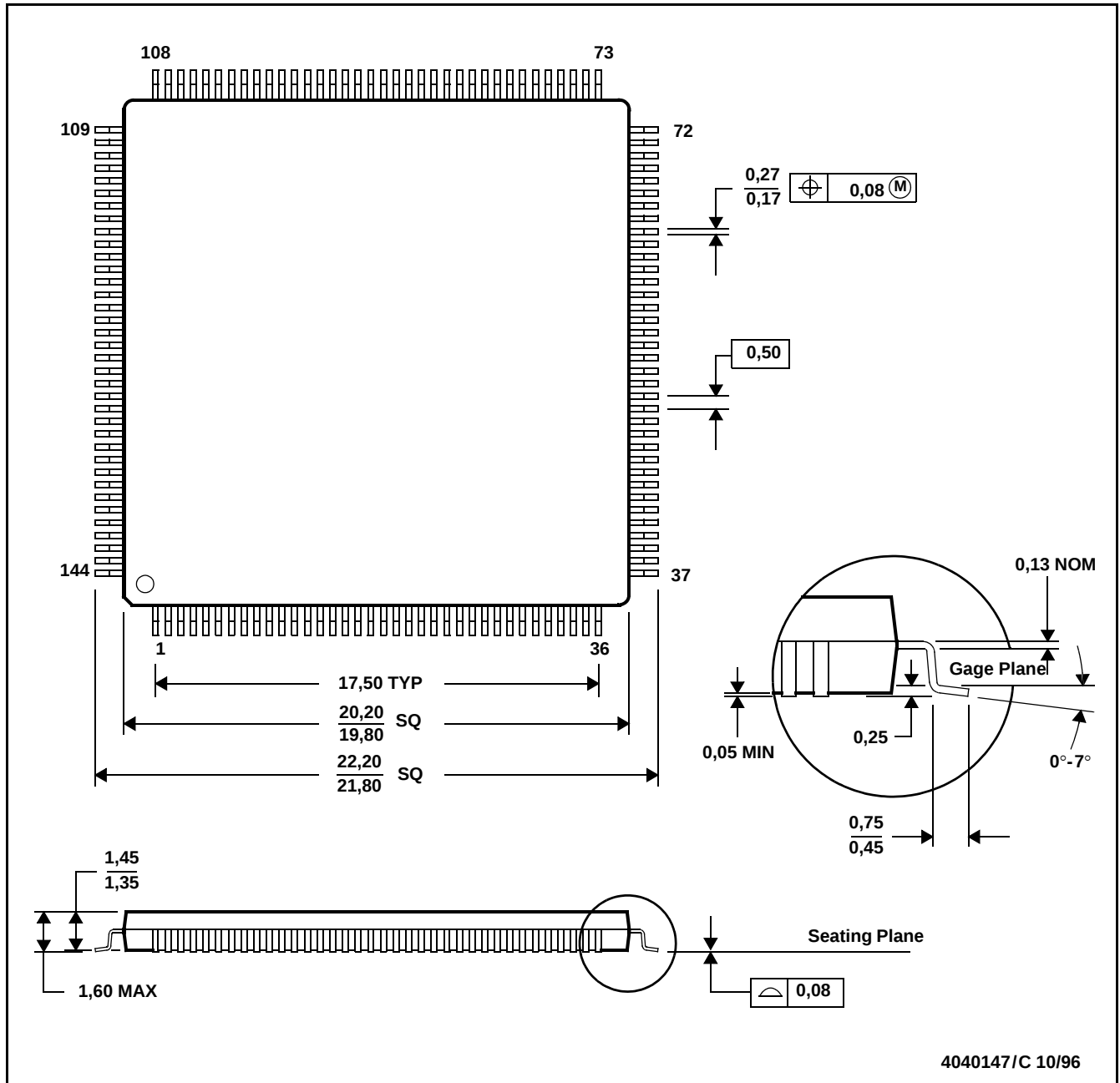
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MECHANICAL DATA

PGE (S-PQFP-G144)

PLASTIC QUAD FLATPACK



- NOTES: A. All linear dimensions are in millimeters.
B. This drawing is subject to change without notice.
C. Falls within JEDEC MS-026

Thermal Resistance Characteristics

PARAMETER	°C/W
$R_{\theta JA}$	43
$R_{\theta JC}$	6.5

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TMS470R1VF55BA
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REVISION HISTORY

REVISION HISTORY

REV	DATE	NOTES
A	8/04	Updates: Page 1, JTAG Boundary-Scan Logic changed to JTAG Test-Access Port Page 1, footnote changed to clarify that boundary scan architecture is not supported on this device Page 22, documentation support section added Page 25, device part numbers for TMS470R1VF55BB/VF55BE added to table Page 25, footnote on part number variations added Page 26, footnote modified to indicate that V_{CCAD} voltage is with respect to V_{SSAD} Page 27, separate V_{IL} and V_{IH} values added for OSCIN Page 33, test condition where N is odd and X is even added to parameters #3 and #4 Page 39 - 41, SPI timing parameters #6 and #7 (minimum values) updated Page 43, SPI timing parameters #4 (maximum value) and #5-7 (minimum value) updated Page 45, SPI timing parameters #5-7 (minimum value) updated Page 51, note changed to indicate that $V_{CCIO} = V_{CCAD} = AD_{REFHI}$

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